R&S®SMA100B RF AND MICROWAVE SIGNAL GENERATOR

Specifications



Data Sheet

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Key features

First class devices thanks to first class signals

- Purest signals
 - Excellent SSB phase noise in base unit: < -120 dBc (typ.) for 10 GHz at an offset of 20 kHz
 - Outstanding SSB phase noise with option: < -132 dBc (typ.) for 10 GHz at an offset of 10 kHz
 - Lowest close-in SSB phase noise: < -83 dBc (typ.); f = 10 GHz, offset = 10 Hz
 - Virtually no wideband noise: < -162 dBc (typ.) at 10 GHz and an offset of 30 MHz
- Lowest harmonic and nonharmonic signal components
 - Very low harmonic signal components over the entire frequency range even at very high output power
 - Very low nonharmonic signal components of < -90 dBc (typ.) at 10 GHz

Very high output power without compromise

- Exceptionally high output level
 - Ultra high output power up to 38 dBm with the 6 GHz model
 - Over 30 dBm at 18 GHz and 28 dBm at 20 GHz with the 20 GHz model
 - More than 30 dBm from 20 GHz to 35 GHz with the 40 GHz model
 - More than 19 dBm up to 70 GHz with the 67 GHz model
- · Excellent level accuracy and repeatability for CW signals, narrow pulses and modulated signals

User friendly in every detail

- Flexible 2 HU or 3 HU housing
- 3 HU with larger 7" display and multiple front panel connectors
- Ergonomic operation thanks to state-of-the-art GUI with touch display

R&S®LegacyPro: refresh your technology

- Plug and play the R&S[®]SMA100B in an automated test system without changing the test software
- Emulation of R&S®SMA100A, R&S®SMF100A, Keysight PSG, Keysight MXG, etc.

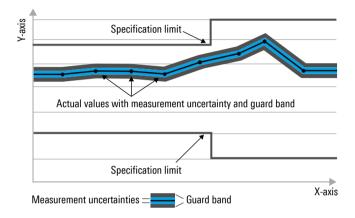
Definitions

General

Product data applies under the following conditions:

- Three hours storage at ambient temperature followed by 30 minutes warm-up operation
- Specified environmental conditions met
- Recommended calibration interval adhered to
- · All internal automatic adjustments performed, if applicable

Specifications with limits



Specifications without limits

Represent warranted product performance for the specified parameter. These specifications are not specially marked and represent values with no or negligible deviations from the given value (e.g. dimensions or resolution of a setting parameter). Compliance is ensured by design.

Typical data (typ.)

Characterizes product performance by means of representative information for the given parameter. When marked with <, > or as a range, it represents the performance met by approximately 80 % of the instruments at production time. Otherwise, it represents the mean value.

Nominal values (nom.)

Characterize product performance by means of a representative value for the given parameter (e.g. nominal impedance). In contrast to typical data, a statistical evaluation does not take place and the parameter is not tested during production.

Measured values (meas.)

Characterize expected product performance by means of measurement results gained from individual samples.

Uncertainties

Represent limits of measurement uncertainty for a given measurand. Uncertainty is defined with a coverage factor of 2 and has been calculated in line with the rules of the Guide to the Expression of Uncertainty in Measurement (GUM), taking into account environmental conditions, aging, wear and tear.

Device settings and GUI parameters are indicated as follows: "parameter: value".

Typical data as well as nominal and measured values are not warranted by Rohde & Schwarz.

Introduction

Frequency options and step attenuator technology

Prerequisite is to install one of the following frequency options.

	Overview of installed step attenuator modules		
Frequency option	Electronic step attenuator up to 20 GHz	Mechanical step attenuator for complete frequency range	
R&S [®] SMAB-B103/-B106/-B112/-B120	•	_	
R&S [®] SMAB-B131/-B140(N)/ -B150(N)/-B167(N)	_	•	
R&S [®] SMAB-B131/-B140(N) with R&S [®] SMAB-B35 option	•	•	
R&S [®] SMAB-B131/-B140(N) with R&S [®] SMAB-B36S option	•	_	
R&S [®] SMAB-B150(N) with R&S [®] SMAB-B37 option	•	•	
R&S [®] SMAB-B167(N) with R&S [®] SMAB-B39 option	•	•	

• = installed, - = not available

If both, electronic and mechanical step attenuators are installed, the electronic step attenuator is used up to 20 GHz as default setting.

If the R&S[®]SMAB-B36S super ultra high output power option is installed, the electronic step attenuator is used up to 20 GHz. Above 20 GHz the mechanical step attenuator is used.

Platform height options and hardware configurations

Depending on the hardware configuration the R&S[®]SMA100B is available with:

2 height units (2 HU; R&S[®]SMAB-B92 option) or

3 height units (3 HU; R&S®SMAB-B93 option).

The height unit option is together with the frequency option a prerequisite.

Frequency option	No high output power option installed	With high output power option	With ultra high output power option	With super ultra high output power option
R&S [®] SMAB-B103	2 or 3 HU	2 or 3 HU	2 or 3 HU	-
R&S [®] SMAB-B106	2 or 3 HU	2 or 3 HU	2 or 3 HU	_
R&S [®] SMAB-B112	2 or 3 HU	2 or 3 HU	2 or 3 HU	-
R&S [®] SMAB-B120	2 or 3 HU	2 or 3 HU	2 or 3 HU	-
R&S [®] SMAB-B131	2 or 3 HU	3 HU	3 HU	3 HU
R&S [®] SMAB-B140, R&S [®] SMAB-B140N	2 or 3 HU	3 HU	3 HU	3 HU
R&S [®] SMAB-B150, R&S [®] SMAB-B150N	2 or 3 HU	3 HU	3 HU	-
R&S [®] SMAB-B167, R&S [®] SMAB-B167N	2 or 3 HU	3 HU	3 HU	-

Frequency, high output power and rear panel connector options

The table shows the frequency options and their corresponding high output power, ultra high output power and rear panel connector options.

Frequency option	Super ultra high output power option			Rear panel connector option
	Ultra high output po	ower option		
	High output power option			
R&S [®] SMAB-B103	R&S [®] SMAB-K31	R&S [®] SMAB-B32	_	R&S [®] SMAB-B80
R&S [®] SMAB-B106	R&S [®] SMAB-K31	R&S [®] SMAB-B32	-	R&S [®] SMAB-B80
R&S [®] SMAB-B112	R&S [®] SMAB-K33	R&S [®] SMAB-B34	_	R&S [®] SMAB-B81
R&S [®] SMAB-B120	R&S [®] SMAB-K33	R&S [®] SMAB-B34	_	R&S [®] SMAB-B81
R&S [®] SMAB-B131	R&S [®] SMAB-B35	R&S [®] SMAB-K36	R&S [®] SMAB-B36S	R&S [®] SMAB-B81
R&S [®] SMAB-B140, R&S [®] SMAB-B140N	R&S [®] SMAB-B35	R&S [®] SMAB-K36	R&S [®] SMAB-B36S	R&S [®] SMAB-B81
R&S [®] SMAB-B150,	R&S [®] SMAB-B37	R&S [®] SMAB-K38	_	R&S [®] SMAB-B82
R&S [®] SMAB-B150N				
R&S [®] SMAB-B167,	R&S [®] SMAB-B39	R&S [®] SMAB-K40	-	R&S [®] SMAB-B82
R&S [®] SMAB-B167N				

Notes:

An ultra high output power option requires the corresponding high output power option to be installed.
 For example, R&S[®]SMAB-K31 is a prerequisite for R&S[®]SMAB-B32.

 R&S[®]SMAB-B36S super ultra high output power option requires R&S[®]SMAB-K36 ultra high output power option and R&S[®]SMAB-B35 high output power option.

RF characteristics

Unless stated otherwise, the specifications apply within the specified level range.

Frequency

Range	R&S [®] SMAB-B103	8 kHz to 3 GHz		
	R&S [®] SMAB-B106	8 kHz to 6 GHz		
	R&S [®] SMAB-B112	8 kHz to 12.75 GHz		
	R&S [®] SMAB-B120	8 kHz to 20 GHz		
	R&S [®] SMAB-B131	8 kHz to 31.8 GHz		
	R&S [®] SMAB-B140/-B140N	8 kHz to 40 GHz		
	R&S [®] SMAB-B150/-B150N	8 kHz to 50 GHz		
	R&S [®] SMAB-B167/-B167N	8 kHz to 67 GHz		
	overrange	67 GHz to 72 GHz		
Resolution of setting	· · · · · · · · · · · · · · · · · · ·	0.001 Hz		
Resolution of synthesis	f = 1 GHz	0.053 nHz (nom.)		
Setting time	CW, to within $< 1 \times 10^{-7}$ for f > 10 MHz or $<$	30 Hz for f < 10 MHz, with GUI update		
-	stopped, after IEC/IEEE bus delimiter (with	stopped, after IEC/IEEE bus delimiter (without LAN connection), with R&S [®] SMAB-B86		
	option, level setting characteristic: auto			
	R&S®SMAB-B103/-B106/-B112/-B120	< 1.7 ms		
	R&S®SMAB-B131/-B140(N)/-B150(N)/	< 2.3 ms		
	-B167(N)			
	with R&S®SMAB-B35/-B36S/-B37/-B39	< 2.5 ms		
	option			
	instruments equipped with R&S [®] SMAB-B711(N) ultra low phase noise option			
	R&S®SMAB-B103/-B106/-B112/-B120	< 4.5 ms		
	R&S®SMAB-B131/-B140(N)/-B150(N)/	< 5 ms		
	-B167(N)			
Resolution of phase offset setting		adjustable in 0.01° steps		
Phase-continuous frequency setting		≥ 1.64 % of set frequency		
range 1	instruments equipped with R&S [®] SMAB-B71	1(N) ultra low phase noise option		
	narrow mode	≥ 0.163 % of set frequency		
	wide mode	≥ 1.47 % of set frequency		
Maximum phase-continuous frequency	synthesizer remains in phase locked state	0.02 % of set frequency (nom.)		
step 1	during frequency step			

Reference frequency

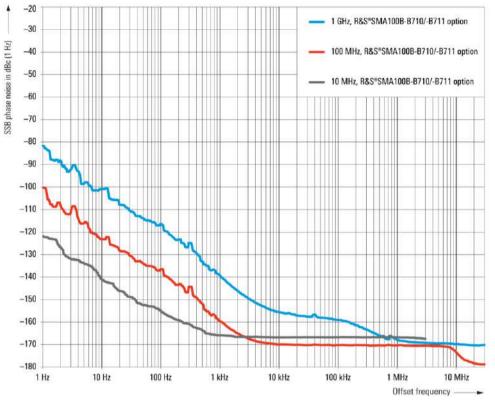
Frequency error	at time of calibration in production	at time of calibration in production		
	standard or with R&S [®] SMAB-B1H/ -B709 option	< 1 × 10 ⁻⁸		
	with R&S [®] SMAB-B710(N)/-B711(N) option	< 5 × 10 ⁻⁹		
Aging	after 30 days of uninterrupted operation			
	standard	≤ 1 × 10 ⁻⁹ /day,		
		≤ 1 × 10 ⁻⁷ /year		
	with R&S [®] SMAB-B1H/-B709/-B710(N)/	≤ 5 × 10 ⁻¹⁰ /day,		
	-B711(N) option	≤ 3 × 10 ⁻⁸ /year		
Temperature effect	in temperature range from 0 °C to +55 °C			
	standard	$\pm 6 \times 10^{-8}$		
	with R&S [®] SMAB-B1H/-B709 option	±6 × 10 ⁻⁹		
	with R&S [®] SMAB-B710(N)/-B711(N)	±3 × 10 ⁻⁹		
	option			
Warm-up time	to nominal thermostat temperature	≤ 10 min (nom.)		

¹ Spectral purity not tested in this mode.

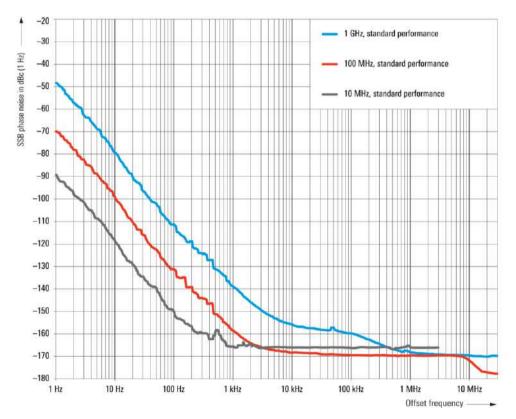
Input for external reference frequenc	У			
Connector type	REF in on rear panel	BNC female		
Input frequency	standard	10 MHz		
	with R&S [®] SMAB-K703 option	10 MHz, 100 MHz		
	with R&S [®] SMAB-K704 option	10 MHz,		
		1 MHz to 100 MHz, variable		
Input frequency setting resolution	with R&S [®] SMAB-K704 option	0.1 Hz		
Input level range	level limits	0 dBm to 20 dBm		
	recommended input level for optimum	7 dBm to 13 dBm		
	phase noise performance			
Input impedance		50 Ω (nom.)		
Minimum frequency locking range	synchronization bandwidth: wide	$\pm 3 \times 10^{-6}$		
, , , , , ,	synchronization bandwidth: narrow			
	standard or with R&S [®] SMAB-B1H/	±0.3 × 10 ⁻⁶		
	-B709 option			
	with R&S [®] SMAB-B710(N)/-B711(N)	±0.15 × 10 ⁻⁶		
	option			
Output for internal reference frequen				
Connector type	REF out on rear panel	BNC female		
Output frequency	standard	sine wave, 10 MHz		
	with R&S [®] SMAB-K703 option	sine wave, 10 MHz, 100 MHz		
	with R&S [®] SMAB-K704 option			
	instrument set to internal reference	sine wave. 10 MHz		
	instrument set to external reference	sine wave, 10 MHz,		
	instrument set to external reference	applied external reference frequency		
Output level		7 dBm to 14 dBm		
Source impedance		50 Ω (nom.)		
Wideband noise	with D& C [®] CMAD KZ02 ontion	< -163 dBc, -167 dBc (typ.)		
wideband hoise	with R&S [®] SMAB-K703 option, 100 MHz, internal reference,	< -163 dBC, -167 dBC (typ.)		
	carrier offset = 10 MHz ,			
	measurement bandwidth: 1 Hz			
Ultra low noise 1 GHz reference frequ				
Input connector type	1 GHz in on rear panel	SMA female		
		1 GHz		
Input frequency	loval limita			
Input level range	level limits	\geq 6 dBm, \leq 20 dBm		
	recommended input level for optimum	7 dBm to 13 dBm		
Innutimpodopoo	phase noise performance	50 Q (nom)		
Input impedance		50Ω (nom.)		
Minimum frequency locking range		$\pm 3 \times 10^{-6}$		
Output connector type	1 GHz out on rear panel	SMA female		
Output frequency		sine wave 1 GHz		
Output level		7 dBm to 13 dBm		
Source impedance		50 Ω (nom.)		
Wideband noise	1 GHz, internal reference,	< -164 dBc, -168 dBc (typ.)		
	carrier offset = 10 MHz,			
	measurement bandwidth: 1 Hz			
Input for electronic tuning of internal				
Connector type	external tune on rear panel	BNC female		
Sensitivity	external tuning slope, low	1 × 10 ⁻⁸ /V (typ.)		
	external tuning slope, high	5 × 10 ⁻⁸ /V (typ.)		
Input voltage range		–10 V to +10 V		
Input impedance		10 kΩ (nom.)		

Overview of synchronization bandwidth of reference PLL with external reference frequency

External reference frequency	Synchronization bandwidth (nominal)	
	Bandwidth set to narrow	Bandwidth set to wide
10 MHz	0.5 Hz	100 Hz
100 MHz (with R&S [®] SMAB-K703 option)	0.5 Hz	250 Hz
Flexible reference input frequency from	0.5 Hz	5 Hz
1 MHz to 100 MHz		
(with R&S [®] SMAB-K704 option)		
1 GHz (with R&S [®] SMAB-K703 option)	5 Hz	> 150 kHz



Measured SSB phase noise of reference outputs at f = 10 MHz, 100 MHz and 1 GHz with the R&S[®]SMAB-B710(N) and R&S[®]SMAB-B711(N) options (f = 100 MHz and 1 GHz only available with the R&S[®]SMAB-K703 option)



Measured SSB phase noise of reference outputs at f = 10 MHz, 100 MHz and 1 GHz (f = 100 MHz and f = 1 GHz are only available with the R&S[®]SMAB-K703 option)

Reference frequency option concept

		Without option	With R&S [®] SMAB-K703 option, 1 GHz reference	With R&S [®] SMAB-K704 option, variable reference input
	10 MHz input frequency	•	•	•
F	100 MHz input frequency	_	•	•
INPUT	1 MHz to 100 MHz input	_	_	•
Ξ	frequency			
	1 GHz input frequency	-	•	-
	10 MHz output frequency	•	•	•
5	100 MHz output frequency	_	•	-
⊢₽	"Loop through" of input to	_	•	•
OUTP	output			
	1 GHz output frequency	-	•	-

R&S[®]SMAB-K703 option (1 GHz reference)

When this option is installed, the user can use the 1 GHz low noise input and output for synchronization. In WIDE mode, the signal generator will use this signal directly as a reference for the synthesizer. This option should be used if a very high phase stability between multiple generators is required. The 100 MHz low noise input and output mode is only available with this option.

R&S[®]SMAB-K704 option (variable reference input)

When this option is installed, the user can set the reference input frequency in 0.1 Hz steps between 1.0 MHz and 100 MHz. The signal generator will lock its internal reference oscillator on the input frequency. The reference output frequency can be set independently from the input frequency.

Note on choosing the proper reference synchronization bandwidth

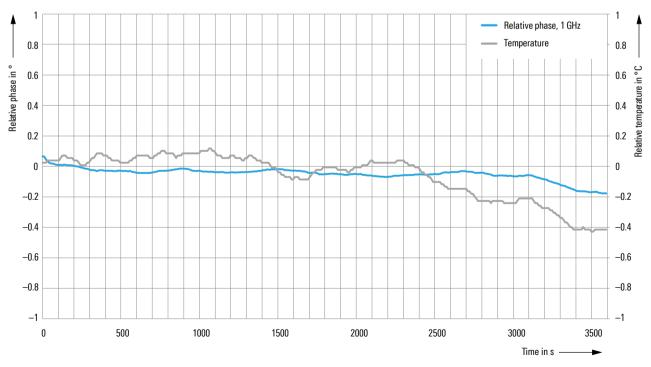
The user has the choice to set the synchronization bandwidth either to NARROW or WIDE.

In WIDE mode, the best possible phase stability is achieved.

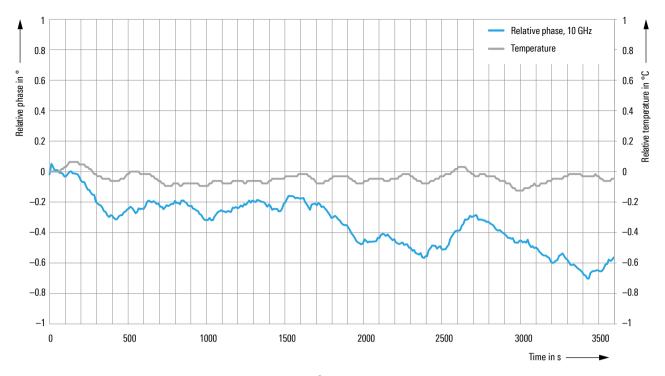
The phase noise performance close to the carrier depends on the phase noise of the external signal source.

In NARROW mode, the reference PLL acts as a clean-up-loop in which the phase noise is mainly determined by the signal generator's internal reference source. This mode is recommended when using external reference sources with close-to-carrier phase noise worse than the R&S[®]SMA100B (i. e. rubidium standards).

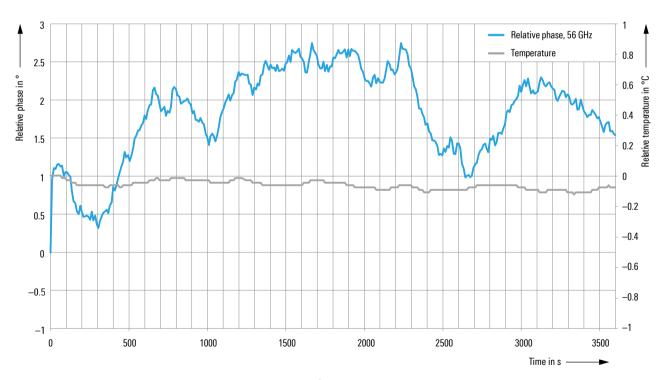
Please note that due to the slow synchronization, reference locking can take up to 10 seconds.



Measured relative phase versus time of two R&S[®]SMA100B instruments at f = 1 GHz carrier frequency, coupled with 1 GHz reference frequency (R&S[®]SMAB-K703 option)



Measured relative phase versus time of two R&S[®]SMA100B instruments at f = 10 GHz carrier frequency, coupled with 1 GHz reference frequency (R&S[®]SMAB-K703 option)



Measured relative phase versus time of two R&S[®]SMA100B instruments at f = 56 GHz carrier frequency, coupled with 1 GHz reference frequency (R&S[®]SMAB-K703 option)

Level

Setting range	ata a da nd		
R&S [®] SMAB-B103/-B106	standard	-145 dBm to +20 dBm	
	with R&S [®] SMAB-K31 option		
	f ≤ 1 MHz	-145 dBm to +30 dBm	
	f > 1 MHz	-145 dBm to +35 dBm	
	with R&S [®] SMAB-B32 option		
	f ≤ 1 MHz	-145 dBm to +30 dBm	
	f > 1 MHz	-145 dBm to +40 dBm	
R&S [®] SMAB-B112/-B120	standard		
	f ≤ 13 GHz	-145 dBm to +19 dBm	
	f > 13 GHz	-145 dBm to +18 dBm	
	with R&S [®] SMAB-K33 option		
	f ≤ 1 MHz	-145 dBm to +30 dBm	
	f > 1 MHz	-145 dBm to +35 dBm	
	with R&S [®] SMAB-B34 option		
	f ≤ 1 MHz	-145 dBm to +30 dBm	
	f > 1 MHz	-145 dBm to +40 dBm	
R&S [®] SMAB-B131/-B140/-B140N	standard		
	f ≤ 18 GHz	-145 dBm to +16 dBm	
	f > 18 GHz	-145 dBm to +15 dBm	
	with R&S®SMAB-B35/-K36/-B36S c	option	
	f ≤ 1 MHz	-145 dBm to +30 dBm	
	f > 1 MHz	-145 dBm to +40 dBm	
R&S [®] SMAB-B150/-B167/	standard		
-B150N/-B167N	f ≤ 20 GHz	-145 dBm to +10 dBm	
	f > 20 GHz	-145 dBm to +7 dBm	
	with R&S [®] SMAB-B37/-B39 option		
	f ≤ 1 MHz	-145 dBm to +30 dBm	
	f > 1 MHz	-145 dBm to +30 dBm	
	with R&S [®] SMAB-B150/-B167/-K38/		
	$f \le 1 \text{ MHz}$	-145 dBm to +30 dBm	
	f > 1 MHz	-145 dBm to +35 dBm	
	with R&S [®] SMAB-B150N/-B167N/-K38/-K40 option		
	$f \le 1 \text{ MHz}$	-145 dBm to +30 dBm	
	$1 \text{ MHz} < f \le 40 \text{ GHz}$	-145 dBm to +35 dBm	
Cotting recolution	f > 40 GHz	-145 dBm to +19 dBm 0.01 dB	
Setting resolution Specified level range	peak envelope power (PEP)	0.01 08	
R&S [®] SMAB-B103/-B106	standard		
R&3-2MAD-D103/-D100	$8 \text{ kHz} < f \le 20 \text{ kHz}$	-90 dBm to +8 dBm	
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm	
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm	
	$1 \text{ MHz} < f \le 6 \text{ GHz}$	-127 dBm to +19 dBm	
	with R&S®SMAB-K31 option		
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm	
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm	
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm	
	$1 \text{ MHz} < f \le 6 \text{ GHz}$	-127 dBm to +25 dBm	
	with R&S [®] SMAB-K31/-B32 option		
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm	
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm	
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm	
	1 MHz < f ≤ 8 MHz	-127 dBm to +25 dBm	
	8 MHz < f ≤ 6 GHz	-127 dBm to +30 dBm	

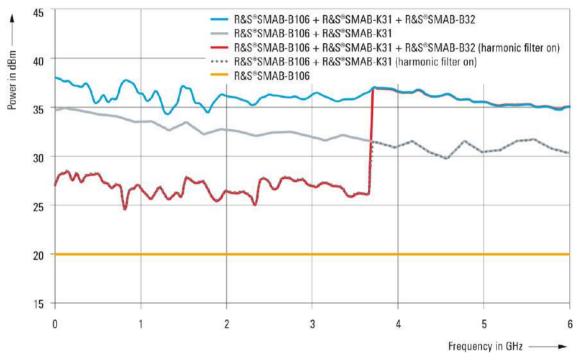
R&S [®] SMAB-B112/-B120	standard	
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm
	1 MHz < f ≤ 6 GHz	-127 dBm to +18 dBm
	6 GHz < f ≤ 13 GHz	-120 dBm to +18 dBm
	13 GHz < f ≤ 20 GHz	-120 dBm to +17 dBm
	with R&S [®] SMAB-K33 option	
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm
	1 MHz < f ≤ 6 GHz	-127 dBm to +23 dBm
	6 GHz < f ≤ 20 GHz	-120 dBm to +20 dBm ²
	with R&S [®] SMAB-K33/-B34 option	
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm
	1 MHz < f ≤ 8 MHz	-127 dBm to +25 dBm
	8 MHz < f ≤ 6 GHz	-127 dBm to +28 dBm
	6 GHz < f ≤ 18 GHz	-120 dBm to +27 dBm ²
	18 GHz < f ≤ 20 GHz	-120 dBm to +24 dBm ²
R&S [®] SMAB-B131/-B140/-B140N	standard	
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm
	100 kHz < f ≤ 1 MHz	-120 dBm to +13 dBm
	1 MHz < f ≤ 18 GHz	-120 dBm to +14 dBm
	18 GHz < f ≤ 40 GHz	-120 dBm to +13 dBm
	with R&S [®] SMAB-B35 option	
	8 kHz < f ≤ 20 kHz	–90 dBm to +8 dBm
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm
	1 MHz < f ≤ 3 GHz	-127 dBm to +22 dBm
	3 GHz < f ≤ 6 GHz	-127 dBm to +18 dBm
	6 GHz < f ≤ 18 GHz	-120 dBm to +18 dBm ²
	18 GHz < f ≤ 37 GHz	-120 dBm to +17 dBm ²
	37 GHz < f ≤ 40 GHz	-120 dBm to +16 dBm ²
	with R&S [®] SMAB-B35/-K36 options	
	8 kHz < f ≤ 20 kHz	–90 dBm to +8 dBm
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm
	1 MHz < f ≤ 3 GHz	-127 dBm to +24 dBm
	3 GHz < f ≤ 6 GHz	-127 dBm to +21 dBm ²
	6 GHz < f ≤ 18 GHz	-120 dBm to +21 dBm ²
	18 GHz < f ≤ 20 GHz	-120 dBm to +20 dBm ²
	20 GHz < f ≤ 33 GHz	-120 dBm to +22 dBm ²
	33 GHz < f ≤ 37 GHz	-120 dBm to +20 dBm ²
	37 GHz < f ≤ 40 GHz	-120 dBm to +19 dBm ²
	with R&S [®] SMAB-B35/-K36/-B36S option	S
	8 kHz < f ≤ 20 kHz	–90 dBm to +8 dBm
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm
	1 MHz < f ≤ 8 MHz	-127 dBm to +24 dBm
	8 MHz < f ≤ 3 GHz	-127 dBm to +29 dBm
	3 GHz < f ≤ 6 GHz	-127 dBm to +28 dBm
	6 GHz < f ≤ 18 GHz	-120 dBm to +24 dBm ²
	18 GHz < f ≤ 20 GHz	-120 dBm to +22 dBm ²
	20 GHz < f ≤ 33 GHz	-120 dBm to +27 dBm ²
	33 GHz < f ≤ 38 GHz	-120 dBm to +26 dBm ²

 $^{^2}$ With the R&S[®]SMAB-B81/-B82 rear panel connectors option, for f > 6 GHz the level is reduced by (0.2 dB + 0.025 dB/GHz).

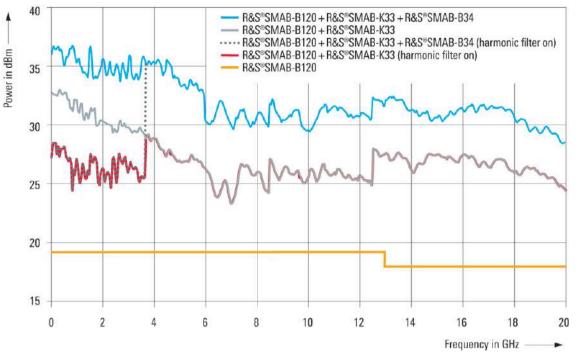
R&S [®] SMAB-B150/-B150N/	standard			
-B167/-B167N	8 kHz < f ≤ 100 kHz	-90 dBm to +8 dBm		
	100 kHz < f ≤ 6 GHz	-95 dBm to +8 dBm		
	6 GHz < f ≤ 20 GHz	-95 dBm to +8 dBm		
	20 GHz < f ≤ 40 GHz	–95 dBm to +5 dBm		
	40 GHz < f ≤ 67 GHz –75 dBm to +5 dBm			
	with R&S [®] SMAB-B37/-B39 option			
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm		
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm		
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm		
	$1 \text{ MHz} < f \le 3 \text{ GHz}$ -127 dBm to +21 dBm			
	$3 \text{ GHz} < f \le 6 \text{ GHz}$	-127 dBm to +18 dBm		
	6 GHz < f ≤ 18 GHz	-120 dBm to +18 dBm ²		
	18 GHz < f ≤ 20 GHz	-120 dBm to +15 dBm ²		
	20 GHz < f ≤ 33 GHz	-95 dBm to +15 dBm ²		
	33 GHz < f ≤ 40 GHz	-95 dBm to +11 dBm ²		
		-75 dBm to +11 dBm ²		
	$40 \text{ GHz} < f \le 65 \text{ GHz}$			
	$65 \text{ GHz} < f \le 67 \text{ GHz}$	-75 dBm to +9 dBm ²		
	with R&S [®] SMAB-B37/-K38/-B39/-K4			
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm		
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm		
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm		
	1 MHz < f ≤ 3 GHz	-127 dBm to +23 dBm		
	3 GHz < f ≤ 6 GHz	-127 dBm to +20 dBm		
	6 GHz < f ≤ 18 GHz	-120 dBm to +20 dBm ²		
	18 GHz < f ≤ 20 GHz	-120 dBm to +17 dBm ²		
	20 GHz < f ≤ 33 GHz	-95 dBm to +18 dBm ²		
	33 GHz < f ≤ 40 GHz	-95 dBm to +15 dBm ²		
	$40 \text{ GHz} < f \le 52 \text{ GHz}$ -95 dBm to +18 dBm ²			
	52 GHz < f ≤ 65 GHz	-75 dBm to +15 dBm ²		
	65 GHz < f ≤ 67 GHz	-75 dBm to +10 dBm ²		
evel accuracy	CW, level setting characteristic: auto, temperature range from +18 °C to +33 °C			
· · · · · · · · · · · · · · · · · · ·	level from –90 dBm to +25 dBm			
	8 kHz < f ≤ 8 MHz	< 1.0 dB		
	8 MHz < f ≤ 3 GHz	< 0.5 dB		
	$3 \text{ GHz} < f \le 20 \text{ GHz}$	< 0.9 dB		
	$20 \text{ GHz} < f \le 40 \text{ GHz}$	< 1.0 dB		
	$40 \text{ GHz} < f \le 50 \text{ GHz}$	< 1.5 dB		
	50 GHz < f ≤ 67 GHz	< 2.0 dB		
	level > +25 dBm			
	8 MHz < f ≤ 18 GHz	< 1.0 dB		
	level < -90 dBm			
	100 kHz < f ≤ 8 MHz	< 1.2 dB		
	8 MHz < f ≤ 3 GHz	< 0.8 dB		
	3 GHz < f ≤ 20 GHz	< 1.2 dB		
	20 GHz < f ≤ 40 GHz	< 1.5 dB		
	40 GHz < f ≤ 50 GHz	< 2.0 dB		
	50 GHz < f ≤ 67 GHz	< 2.5 dB		
nterruption-free level setting range	level setting characteristic:	> 20 dB		
	uninterrupted level setting			
	with R&S [®] SMAB-K724 option,			
	level setting characteristic: high dyna	amic uninterrupted		
	f > 52 MHz	> 60 dB, 70 dB (typ.)		
dditional level error	ALC state off (table)	< 0.7 dB		
	with R&S [®] SMAB-K724 option, level setting characteristic: high dynamic uninterrupted, temperature range from +18 °C to +33 °C, specifications are measured for f > 40 GHz			
		55 C, specifications are measured for t > 40 GHz		
	attenuation range			
	0 dB < m ≤ 10 dB	< 0.25 dB		
	10 dB < m ≤ 20 dB	< 1 dB		
	20 dB < m ≤ 40 dB	< 2 dB (typ.)		
	$40 \text{ dB} < m \le 50 \text{ dB}$ $50 \text{ dB} < m \le 60 \text{ dB}$	< 3 dB (typ.) < 4 dB (typ.)		

Version 07.01, August 2022

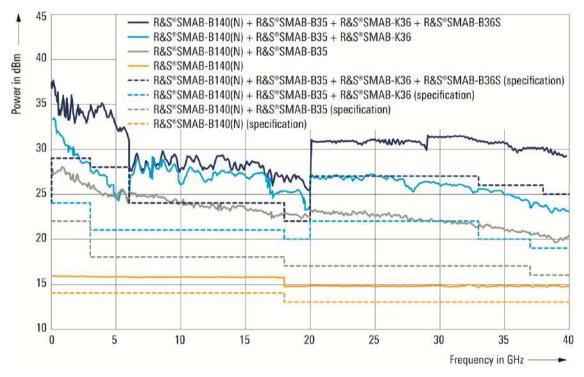
Setting time	range from +18 °C to +33 °C, after IEC/IE	CW, level deviation < 0.1 dB from final value, with GUI update stopped, temperature range from +18 °C to +33 °C, after IEC/IEEE bus delimiter (without LAN connection), with R&S [®] SMAB-B86 option, level setting characteristic: auto, no relay switchover		
	R&S [®] SMAB-B103/-B106/-B112/-B120	< 1.5 ms		
	R&S [®] SMAB-B131/-B140(N)/-B150(N)/	< 1.7 ms		
	-B167(N)			
	with switching of mechanical step attenuator	< 25 ms		
Level setting characteristics	predefined modes to optimize the instrument behavior for common applications	auto uninterrupted level setting strictly monotone constant VSWR		
Automatic level control modes		auto, on, off (table), table and on		



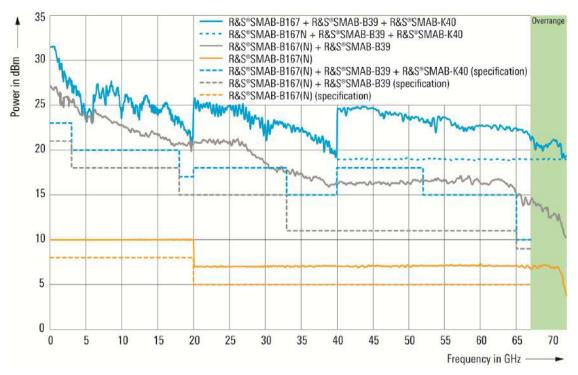
Measured maximum available output power versus frequency



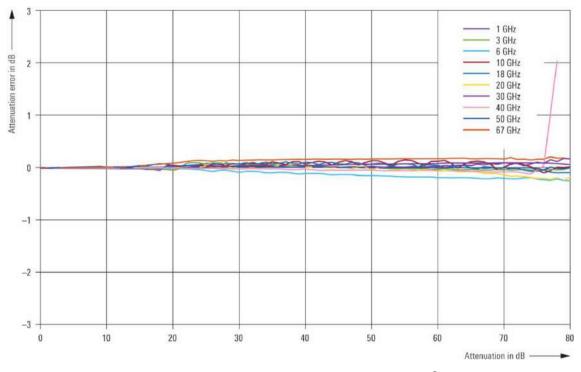
Measured maximum available output power versus frequency



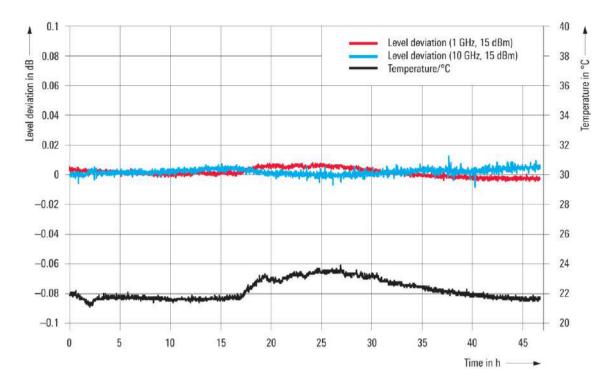
Specified and measured maximum available output power versus frequency



Specified and measured maximum available output power versus frequency



Measured level linearity of high dynamic uninterrupted level sweep with the R&S®SMAB-K724 option



Measured level repeatability and ambient temperature over 46 h. The figure shows the very high level repeatability at 15 dBm output level for 1 GHz and 10 GHz carrier frequency. During two consecutive measurements, the output level was set to different random level values

Reverse power

Reverse power (from 50 Ω source)	maximum permissible reverse RF power with R&S [®] SMAB-B103/-B106;		
	in case of too high reverse power, the RF output is switched off by a mechanical relay		
	$1 \text{ MHz} < f \le 3 \text{ GHz}$	50 W	
	3 GHz < f < 6 GHz	10 W	
	maximum permissible reverse RF power with R&S®SMAB-B112/-B120/-B131/-B140/		
	-B140N/-B150/-B150N/-B167/-B167N		
	1 MHz < f ≤ 67 GHz	0.5 W	
Maximum permissible DC voltage	R&S [®] SMAB-B103/-B106	50 V	
	R&S [®] SMAB-B112/-B120	5 V	
	R&S [®] SMAB-B131/-B140/-B140N/-B150/	1 V	
	-B150N/-B167/-B167N		

VSWR

Output impedance VSWR in 50 Ω system,	R&S [®] SMAB-B103/-B106		
ALC state auto	200 kHz < f ≤ 6 GHz	< 1.6	
	R&S [®] SMAB-B112/-B120		
	200 kHz < f ≤ 3 GHz	< 1.9 (meas.)	
	3 GHz < f ≤ 6 GHz	< 1.7 (meas.)	
	6 GHz < f ≤ 20 GHz	< 1.6 (meas.)	
	R&S [®] SMAB-B112/-B120 with R&S [®] SMAB-	B34	
	200 kHz < f ≤ 3 GHz	< 1.9 (meas.)	
	3 GHz < f ≤ 6 GHz	< 1.7 (meas.)	
	6 GHz < f ≤ 20 GHz	< 1.8 (meas.)	
	R&S [®] SMAB-B131/-B140/-B140N/-B150/-B1	150N/-B167/-B167N	
	200 kHz < f ≤ 3 GHz	< 1.9 (meas.)	
	3 GHz < f ≤ 50 GHz	< 2.0 (meas.)	

Frequency and level sweep

Operating mode		digital sweep in discrete steps		
Sweep parameters		RF frequency,		
		RF level,		
		RF frequency and RF level		
Trigger modes	execute sweep continuously with internal	auto		
	trigger source			
	execute one full sweep	single		
	execute one step	step		
	sweep start and stop controlled by	start/stop		
	external trigger signal			
Trigger source		external trigger signal (INST TRIG		
		at rear), rotary knob, touch panel,		
		remote fcontrol		
Sweep range		full specified frequency and level range		
	interruption-free level sweep with	0.01 dB to 20 dB		
	attenuator mode fixed			
	high dynamic uninterrupted level sweep with R&S [®] SMAB-K724 option			
	f > 52 MHz	0.01 dB to 60 dB, 70 dB (typ.)		
Sweep shape		sawtooth, triangle		
Step size setting resolution	frequency sweep linear	0.001 Hz		
	frequency sweep logarithmic	0.01 %		
	level sweep	0.01 dB		
Dwell time setting range	RF level sweep	3 ms to 100 s		
-	RF frequency sweep	3 ms to 100 s		
	with R&S [®] SMAB-B711(N) option	5 ms to 100 s		
Dwell time setting resolution		0.1 ms		

Ramp sweep (R&S[®]SMAB-B28 option)

Operating mode		synthesized frequency sweep (up
		direction)
Trigger modes	execute sweep continuously	auto
	execute one full sweep	single
Trigger source		external trigger signal (INST TRIG
		at rear), rotary knob, touchpanel,
		remote control
Sweep span range		Ramp sweep frequency range
Maximum sweep rate	f ≤ 375 MHz	500 MHz/ms
	375 MHz < f ≤ 750 MHz	31.25 MHz/ms
	750 MHz < f ≤ 1500 MHz 62.5 MHz/ms	
	1.5 GHz < f ≤ 3 GHz 125 MHz/ms	
	3 GHz < f ≤ 6 GHz	250 MHz/ms
	6 GHz < f ≤ 12 GHz	500 MHz/ms
	12 GHz < f ≤ 24 GHz	1 GHz/ms
	24 GHz < f ≤ 48 GHz	2 GHz/ms
	48 GHz < f ≤ 67 GHz	4 GHz/ms
Frequency accuracy		(0.005 % of span) / (sweep time/s)
Sweep time		
Setting range		10 ms to 100 s
Setting resolution		0.1 ms
Frequency markers	number of frequency markers	10

List mode

Frequency and level values can be stored in a list and triggered by an internal timer or an external trigger.

Run mode		live
Operating modes	internal trigger, infinite	auto
	internal trigger, one sweep per trigger event	single
	internal trigger, one step per trigger event	step
	external trigger, one sweep per trigger event	extern single
	external trigger, one step per trigger event	extern step
Dwell time setting range	can be set individually for each step	1 ms to 100 s
Dwell time setting resolution		0.1 ms

Spectral purity

Harmonics ³	CW			
R&S [®] SMAB-B103/-B106	level = 10 dBm;	level = 10 dBm;		
	for instruments equipped with R&S [®] SMAB-B32 ultra high output power option:			
	level = 18 dBm			
	100 kHz ≤ f ≤ 10 MHz	< –30 dBc		
	f > 10 MHz	< -60 dBc		
R&S [®] SMAB-B112/-B120	level = 10 dBm:			
		S [®] SMAB-B34 ultra high output power option:		
	level = 16 dBm	• •····· = = • • •····· ···· ···· ····		
	$100 \text{ kHz} \le f \le 10 \text{ MHz}$	< -30 dBc		
	f > 10 MHz	< -55 dBc		
R&S [®] SMAB-B131/-B140/-B140N/		fied output power, whichever is lower;		
-B150/-B150N/-B167/-B167N		output power option, ultra high output power option		
	or super ultra high output power of			
	100 kHz \leq f \leq 10 MHz	< -30 dBc		
	f > 10 MHz	< -55 dBc		
Nonharmonics	CW, offset > 10 kHz from carrier,			
Normannonics		fied output power, whichever is lower		
	$f \le 750 \text{ MHz}$	< -96 dBc		
		< -90 dBc		
	750 MHz < f ≤ 1.5 GHz 1.5 GHz < f ≤ 3 GHz			
	$3 \text{ GHz} < f \le 3 \text{ GHz}$	< -86 dBc		
		< -80 dBc		
	$6 \text{ GHz} < f \le 12 \text{ GHz}$	< -74 dBc		
	$12 \text{ GHz} < f \le 24 \text{ GHz}$	< -68 dBc		
	24 GHz < f ≤ 48 GHz	< -62 dBc		
	f > 48 GHz	< -56 dBc		
	for instruments equipped with R&S [®] SMAB-B711(N) ultra low phase noise option:			
	CW, offset > 10 kHz from carrier,			
		fied output power, whichever is lower		
	f ≤ 1.5 GHz	< -100 dBc		
	1.5 GHz < f ≤ 3 GHz	< -94 dBc		
	3 GHz < f ≤ 6 GHz	< -88 dBc		
	6 GHz < f ≤ 12 GHz	< -82 dBc		
	12 GHz < f ≤ 24 GHz	< –76 dBc		
	24 GHz < f ≤ 48 GHz	< –70 dBc		
	f > 48 GHz	< –64 dBc		
Subharmonics ⁴	CW, level operating mode: auto,			
		fied output power, whichever is lower		
	f ≤ 5 GHz	< -85 dBc,		
		< -95 dBc with R&S [®] SMAB-B711(N) option		
	5 GHz < f ≤ 20 GHz	< -60 dBc		
	20 GHz < f ≤ 50 GHz	< -60 dBc		
	f > 50 GHz	< -60 dBc (meas.)		

³ Specifications are not valid for harmonics beyond "specified frequency range" or above 50 GHz.

⁴ Specifications are not valid for subharmonics beyond "specified frequency range" or above 50 GHz.

Wideband noise		level operating mode: auto, measurement bandwidth: 1 Hz, CW;				
		level = 10 dBm or maximum available output power, whichever is lower				
		carrier offset: 10 MHz or 10 % of carrier frequency, whichever is lower				
	$f \le 8 \text{ MHz}$	< -150 dBc				
	8 MHz < f ≤ 1.5 GHz	< -155 dBc				
	1.5 GHz < f ≤ 3 GHz	< -153 dBc				
	3 GHz < f ≤ 6.0 GHz	< –150 dBc				
	carrier offset: 40 MHz					
	6.0 GHz < f ≤ 12 GHz	< –150 dBc				
	12 GHz < f ≤ 20 GHz	< -145 dBc				
	20 GHz < f ≤ 40 GHz	< -145 dBc (typ.)				
	40 GHz < f ≤ 50 GHz	< –140 dBc (typ.)				
	f > 50 GHz	–142 dBc (meas.)				
	instruments equipped with R&S [®] SN	IAB-B711(N) ultra low phase noise option				
	carrier offset: 10 MHz or 10 % o	f carrier frequency, whichever is lower				
	f ≤ 8 MHz	< –150 dBc				
	8 MHz < f ≤ 1.5 GHz	< –157 dBc				
	1.5 GHz < f ≤ 3 GHz	< –155 dBc				
	3 GHz < f ≤ 6.0 GHz	< –155 dBc				
	carrier offset: 30 MHz	carrier offset: 30 MHz				
	6.0 GHz < f ≤ 12 GHz	< –154 dBc				
	12 GHz < f ≤ 16 GHz	< –152 dBc (typ.)				
	carrier offset: 40 MHz					
	16 GHz < f ≤ 20 GHz	< -152 dBc (typ.)				
	20 GHz < f ≤ 40 GHz	< -145 dBc (typ.)				
	40 GHz < f ≤ 50 GHz	< -140 dBc (typ.)				
	f > 50 GHz	-142 dBc (meas.)				
SSB phase noise	for standard instruments or equippe					
		CW, carrier offset: 20 kHz, measurement bandwidth: 1 Hz, level = 10 dBm or maximum				
	available output power, whichever i					
	f = 10 MHz ⁵	< -158 dBc, -165 dBc (typ.)				
	f = 100 MHz	< -154 dBc, -159 dBc (typ.)				
	f = 1 GHz	< -135 dBc, -140 dBc (typ.)				
	f = 2 GHz	< -129 dBc, -134 dBc (typ.)				
	f = 3 GHz	<pre>< -125 dBc, -130 dBc (typ.)</pre>				
	f = 4 GHz	< -123 dBc, -128 dBc (typ.)				
	f = 6 GHz	 < -119 dBc, -124 dBc (typ.) 				
	f = 10 GHz	<pre>< -115 dBc, -124 dBc (typ.)</pre>				
	f = 20 GHz	<pre>< -109 dBc, -114 dBc (typ.)</pre>				
	f = 40 GHz	<pre>< -109 dBc, -114 dBc (typ.)</pre> < -103 dBc, -108 dBc (typ.)				
	f = 50 GHz	<pre>< -103 dBc, -108 dBc (typ.)</pre> < -101 dBc, -106 dBc (typ.)				

⁵ For instruments equipped with R&S[®]SMAB-B131/-B140(N)/-B150(N)/-B167(N) frequency options, the specified phase noise values at 10 MHz RF frequency show the typical performance.

SSB phase noise with R&S[®]SMAB-B709 option

Specified values in plain text, measured values in brackets () and italics.

SSB phase noise in dBc	(1 Hz), CW, level = 10 d	Bm or maximum available	output power, whichever	is lower
Offset frequency Carrier frequency	1 Hz	10 Hz	100 Hz	1 kHz
f = 10 MHz ⁶	(–98)	-120	–136	-147
f = 100 MHz	(-79)	-103	–124	-144
f = 1 GHz	(–59)	-83	-104	-124
f = 2 GHz	(–53)	-77	-98	–118
f = 3 GHz	(–49)	-73	-94	-114
f = 4 GHz	(–47)	-71	-92	-112
f = 6 GHz	(–43)	-67	-88	-108
f = 10 GHz	(–39)	-63	-84	-104
f = 20 GHz	(–33)	-58	-78	-98
f = 40 GHz	(–27)	-52	-72	-92
f = 50 GHz	(–25)	-50	-70	-90
f = 67 GHz	(–22)	-47	-67	-87

SSB phase noise in dBc	: (1 Hz), CW, level = 10 d	Bm or maximum availabl	e output power, whichever	is lower
Offset frequency	10 kHz	100 kHz	1 MHz	10 MHz
Carrier frequency				
f = 10 MHz ⁶	–157	-160	–161	
f = 100 MHz	–155	-155	-162	-162
f = 1 GHz	-140	-138	-145	-160
f = 2 GHz	-134	-132	–139	-159
f = 3 GHz	-130	-128	–136	-159
f = 4 GHz	-128	-126	–133	–157
f = 6 GHz	-124	-122	–131	-156
f = 10 GHz	-120	–118	–124	-148
f = 20 GHz	–114	–112	–118	-142
f = 40 GHz	-108	-106	–112	-136
f = 50 GHz	-106	-104	–110	-134
f = 67 GHz	-103	-101	-107	–131

SSB phase noise with R&S[®]SMAB-B710(N) option

Specified values in plain text, typical values in brackets (), measured values in brackets () and italics. Specifications above 3 GHz only applicable for R&S[®]SMAB-B710 option.

SSB phase noise in dBo	SSB phase noise in dBc (1 Hz), CW, level = 10 dBm or maximum available output power, whichever is lower					
Offset frequency Carrier frequency	1 Hz	10 Hz	100 Hz	1 kHz		
f = 10 MHz ⁶	(–116)	-124 (-130)	-136 (-141)	-147 (-154)		
f = 100 MHz	(-101)	-117 (-122)	-129 (-136)	-144 (-152)		
f = 1 GHz	(-82)	-97 (-103)	-111 (-117)	-131 (-139)		
f = 2 GHz	(–76)	-91 (-97)	-105 (-111)	-125 (-132)		
f = 3 GHz	(–72)	-87 (-93)	-101 (-108)	-121 (-129)		
f = 4 GHz	(-70)	-86 (-91)	-99 (-106)	-119 (-127)		
f = 6 GHz	(–66)	-81 (-87)	-95 (-102)	-115 (-123)		
f = 10 GHz	(-62)	-77 (-83)	-91 (-97)	-111 (-119)		
f = 20 GHz	(-56)	-71 (-77)	-85 (-91)	-105 (-113)		
f = 40 GHz	(-50)	-65 (-71)	-79 (-85)	-99 (-107)		
f = 50 GHz	(-47)	-63 (-69)	-77 (-83)	-97 (-104)		
f = 67 GHz	(-44)	-60 (-66)	-74 (-81)	-94 (-102)		

⁶ For instruments equipped with R&S[®]SMAB-B131/-B140(N)/-B150(N)/-B167(N) frequency options, the specified phase noise values at 10 MHz RF frequency show the typical performance.

SSB phase noise in dBo	: (1 Hz), CW, level = 10	dBm or maximum ava	ilable output power, whic	hever is lower
Offset frequency	10 kHz	100 kHz	1 MHz	10 MHz
Carrier frequency	457 (400)	400 (405)	404 (400)	
f = 10 MHz ⁷	–157 (–163)	–160 (–165)	-161 (-166)	
f = 100 MHz	–155 (–161)	-155 (-160)	-162 (-166)	-162 (-169)
f = 1 GHz	–140 (–145)	-138 (-143)	-145 (-150)	-160 (-165)
f = 2 GHz	-134 (-139)	-132 (-137)	-139 (-144)	-159 (-165)
f = 3 GHz	–130 (–135)	-128 (-134)	-136 (-143)	-159 (-165)
f = 4 GHz	-128 (-133)	-126 (-131)	-133 (-138)	-157 (-161)
f = 6 GHz	-124 (-130)	-122 (-129)	-131 (-137)	-156 (-160)
f = 10 GHz	-120 (-125)	-118 (-123)	-124 (-130)	-148 (-153)
f = 20 GHz	–114 (–119)	–112 (–117)	-118 (-124)	-142 (-147)
f = 40 GHz	-108 (-113)	-106 (-111)	-112 (-118)	-136 (-141)
f = 50 GHz	-106 (-111)	-104 (-109)	-110 (-116)	-134 (-139)
f = 67 GHz	–103 (–110)	-101 (-106)	-107 (-113)	-131 (-136)

SSB phase noise with R&S[®]SMAB-B711(N) option

Specified values in plain text, typical values in brackets (), measured values in brackets () and italics. Specifications above 3 GHz only applicable for R&S[®]SMAB-B711 option.

SSB phase noise in dBc	(1 Hz), CW, level = 10 d	Bm or maximum available	output power, whichever	is lower
Offset frequency	1 Hz	10 Hz	100 Hz	1 kHz
Carrier frequency				
f = 10 MHz ⁷	(–116)	-124 (-130)	-136 (-141)	-147 (-154)
f = 100 MHz	(-101)	-117 (-122)	-129 (-136)	-146 (-152)
f = 1 GHz	(-82)	-97 (-103)	–111 (–117)	–135 (–139)
f = 2 GHz	(-76)	-91 (-97)	-105 (-111)	-129 (-133)
f = 3 GHz	(-72)	-87 (-93)	-101 (-108)	–125 (–130)
f = 4 GHz	(-70)	-86 (-91)	-99 (-106)	-122 (-127)
f = 6 GHz	(-66)	-81 (-87)	-95 (-102)	-119 (-124)
f = 10 GHz	(-62)	-77 (-83)	-91 (-97)	–115 (–120)
f = 20 GHz	(–56)	-71 (-77)	-85 (-91)	-109 (-114)
f = 40 GHz	(-50)	-65 (-71)	-79 (-85)	-103 (-107)
f = 50 GHz	(-47)	-63 (-69)	-77 (-83)	-101 (-105)
f = 67 GHz	(-44)	-60 (-66)	-74 (-81)	-98 (-103)

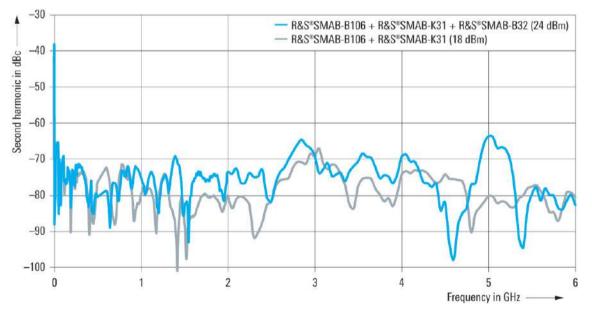
SSB phase noise in dBo	SSB phase noise in dBc (1 Hz), CW, level = 10 dBm or maximum available output power, whichever is lower			
Offset frequency	10 kHz	100 kHz	1 MHz	10 MHz
Carrier frequency				
f = 10 MHz ⁷	–157 (–163)	-160 (-166)	-161 (-166)	
f = 100 MHz	–155 (–161)	-162 (-166)	-162 (-167)	-162 (-168)
f = 1 GHz	–147 (–151)	-148 (-153)	-157 (-162)	-160 (-165)
f = 2 GHz	-142 (-145)	-142 (-147)	-151 (-158)	-159 (-165)
f = 3 GHz	-138 (-142)	-138 (-144)	-148 (-157)	-159 (-164)
f = 4 GHz	–135 (–139)	-136 (-141)	-147 (-152)	-157 (-162)
f = 6 GHz	–132 (–136)	-132 (-138)	-144 (-151)	-155 (-161)
f = 10 GHz	-128 (-132)	-128 (-134)	-140 (-146)	-156 (-160)
f = 20 GHz	–122 (–126)	-122 (-128)	-134 (-140)	-148 (-153)
f = 40 GHz	–115 (–119)	-116 (-121)	-128 (-133)	-142 (-146)
f = 50 GHz	–112 (–116)	-114 (-119)	-126 (-130)	(-143) (-145)
f = 67 GHz	–110 (–114)	–111 (–117)	-123 (-128)	(-140) (-142)

⁷ For instruments equipped with frequency options R&S[®]SMAB-B131/-B140(N)/-B150(N)/-B167(N), the specified phase noise values at 10 MHz RF frequency show the typical performance.

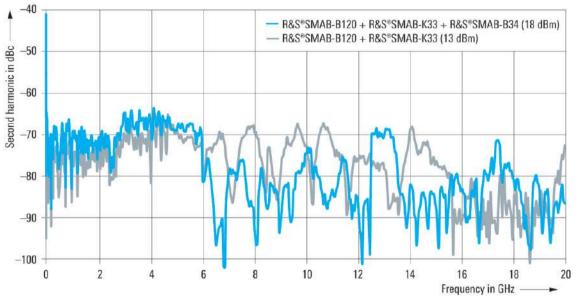
RMS jitter

Specifications above 3 GHz not applicable for R&S®SMAB-B710N and R&S®SMAB-B711N options.

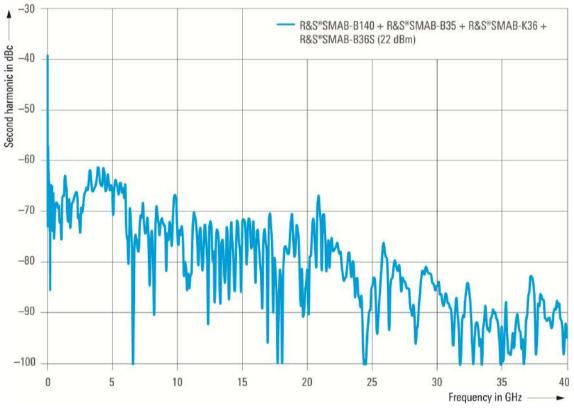
RMS jitter	f = 155 MHz, BW = 100 Hz to 1.5 MHz	20.1 fs (meas.)
	f = 622 MHz, BW = 1 kHz to 5 MHz	18.7 fs (meas.)
	f = 1 GHz, BW = 1 Hz to 10 MHz	558 fs (meas.)
	f = 2.488 GHz, BW = 5 kHz to 20 MHz	18.7 fs (meas.)
	f = 9.952 GHz, BW = 10 kHz to 80 MHz	18.5 fs (meas.)
With R&S [®] SMAB-B1H option	f = 155 MHz, BW = 100 Hz to 1.5 MHz	19.7 fs (meas.)
	f = 622 MHz, BW = 1 kHz to 5 MHz	18.8 fs (meas.)
	f = 1 GHz, $BW = 1 Hz$ to 10 MHz	129 fs (meas.)
	f = 2.488 GHz, BW = 5 kHz to 20 MHz	18.7 fs (meas.)
	f = 9.952 GHz, BW = 10 kHz to 80 MHz	18.5 fs (meas.)
With R&S [®] SMAB-B709 option	f = 155 MHz, BW = 100 Hz to 1.5 MHz	18.5 fs (meas.)
	f = 622 MHz, BW = 1 kHz to 5 MHz	13.6 fs (meas.)
	f = 1 GHz, $BW = 1 Hz$ to 10 MHz	129 fs (meas.)
	f = 2.488 GHz, BW = 5 kHz to 20 MHz	13.6 fs (meas.)
	f = 9.952 GHz, BW = 10 kHz to 80 MHz	13.1 fs (meas.)
With R&S [®] SMAB-B710(N) option	f = 155 MHz, BW = 100 Hz to 1.5 MHz	18.5 fs (meas.)
	f = 622 MHz, BW = 1 kHz to 5 MHz	13.6 fs (meas.)
	f = 1 GHz, $BW = 1 Hz$ to 10 MHz	21.3 fs (meas.)
	f = 2.488 GHz, BW = 5 kHz to 20 MHz	13.6 fs (meas.)
	f = 9.952 GHz, BW = 10 kHz to 80 MHz	13.1 fs (meas.)
With R&S [®] SMAB-B711(N) option	f = 155 MHz, BW = 100 Hz to 1.5 MHz	8.4 fs (meas.)
	f = 622 MHz, BW = 1 kHz to 5 MHz	5.1 fs (meas.)
	f = 1 GHz, $BW = 1 Hz$ to 10 MHz	17.5 fs (meas.)
	f = 2.488 GHz, BW = 5 kHz to 20 MHz	4.1 fs (meas.)
	f = 9.952 GHz, BW = 10 kHz to 80 MHz	3.8 fs (meas.)
Residual FM	RMS values at f = 1 GHz	
	0.3 kHz to 3 kHz, weighted (ITU-T)	< 1 Hz
	0.03 kHz to 23 kHz	< 4 Hz
Residual AM	level = 8 dBm, $f \le 41$ GHz,	< 0.02 %
	RMS value (0.03 kHz to 20 kHz)	



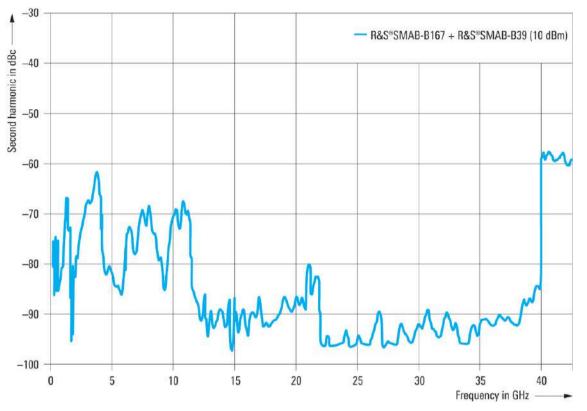
Measured harmonics versus carrier frequency with harmonic filter on for f \leq 3.7 GHz



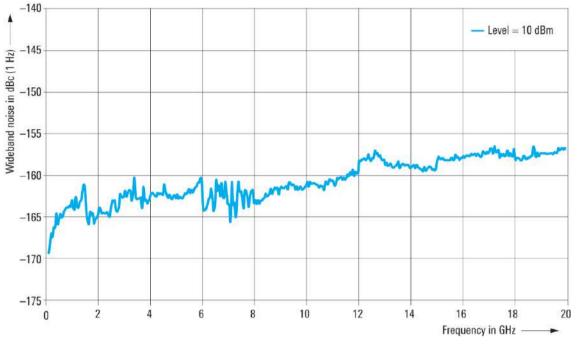
Measured harmonics versus carrier frequency with harmonic filter on for f ≤ 3.7 GHz



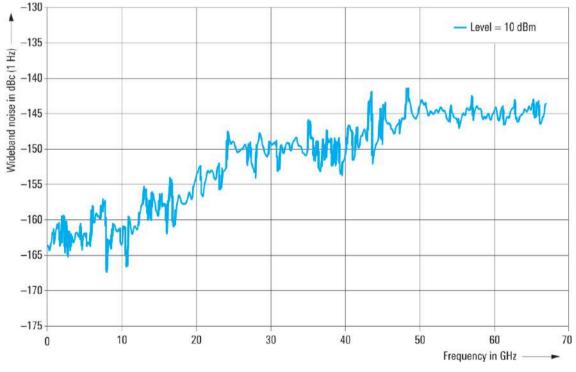
Measured harmonics versus carrier frequency with harmonic filter on for f \leq 3.7 GHz



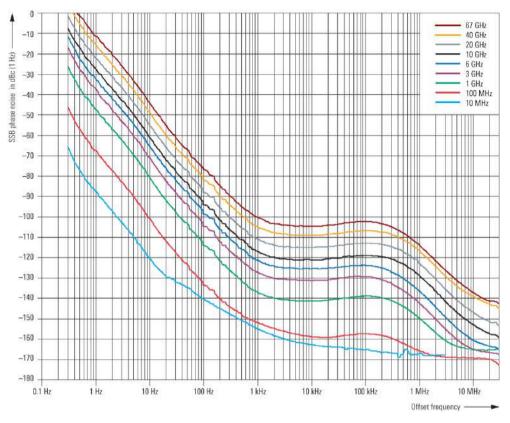
Measured harmonics versus carrier frequency with harmonic filter on for $f \le 3.7$ GHz



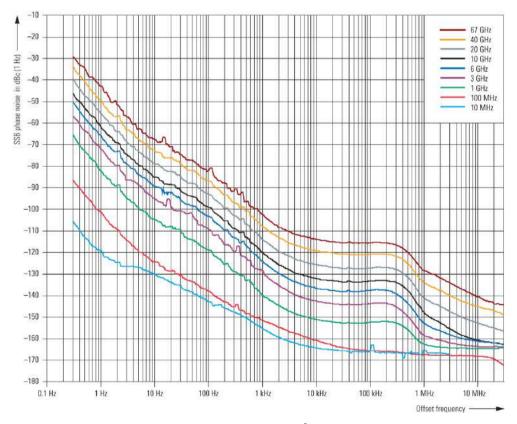
Measured wideband noise at 30 MHz offset and +10 dBm versus carrier frequency with the R&S®SMAB-B120, R&S®SMAB-B711 and R&S®SMAB-B34 options. Measured with the R&S®FSWP phase noise analyzer



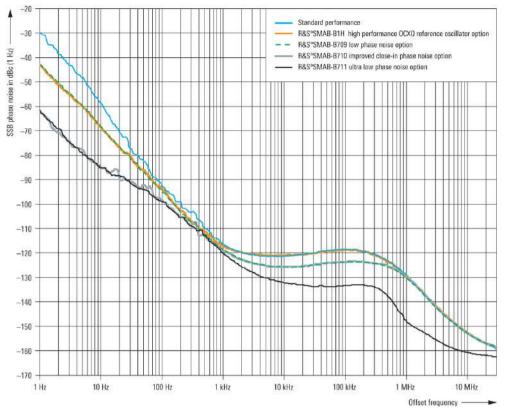
Measured wideband noise at 70 MHz offset and +10 dBm versus carrier frequency with the R&S[®]SMAB-B167, R&S[®]SMAB-B711 and R&S[®]SMAB-B39 options. Measured with the R&S[®]FSW85 spectrum analyzer



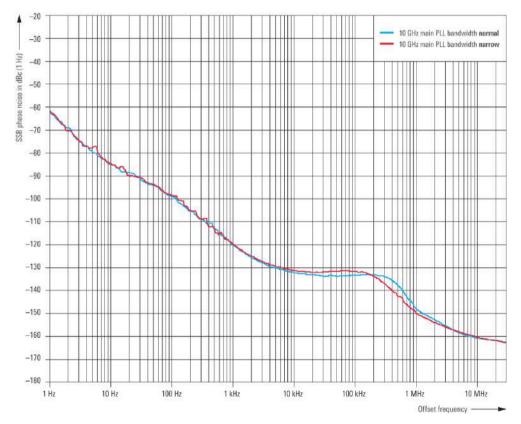
Measured SSB phase noise (standard performance)



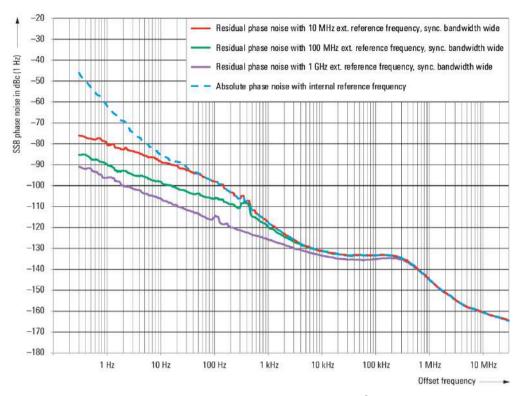
Measured SSB phase noise with the R&S[®]SMAB-B711(N) option



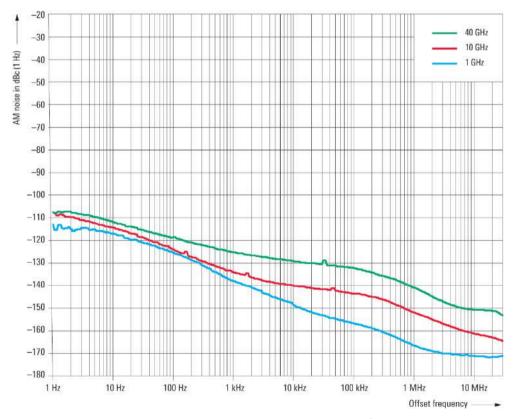
Measured SSB phase noise at f = 10 GHz, standard performance versus the R&S[®]SMAB-B1H, R&S[®]SMAB-B709, R&S[®]SMAB-B710 and R&S[®]SMAB-B711 options



Measured SSB phase noise at f = 10 GHz, comparison of PLL bandwidth normal and narrow with the R&S[®]SMAB-B711 option



Measured residual SSB phase noise at f = 10 GHz with the R&S[®]SMAB-B711 option; comparison of different reference frequencies against absolute phase noise



Measured AM noise at f = 1 GHz, 10 GHz and 40 GHz with the R&S[®]SMAB-B711 option

Analog modulation

Simultaneous modulation

Can be simultaneously combined with \rightarrow	AM	Scan AM	FM	φΜ	Pulse modulation	Chirped pulses
	0	-	•	-	•	_
AM	0	-	•	-	-	•
Alvi	0	-	_	•	•	_
	0	-	_	•	-	•
	-	0	•	-	•	_
Scan AM	—	0	•	_	_	٠
Scall Alvi	-	0	_	•	•	_
	-	0	_	•	-	•
	•	_	0	-	•	_
FM	•	_	0	-	-	•
I IVI	—	•	0	_	•	—
	-	•	0	_	_	•
	•	-	—	0	•	—
φM	•	_	_	0	-	•
ψινι	_	•	_	0	•	_
	_	•	_	0	-	•
	•	-	•	_	-	_
Pulse modulation or	•	_	_	•	_	_
Chirped pulses	—	•	•	_	-	_
	_	•	_	•	_	_

• = compatible, – = incompatible, \circ = compatible with limitations

With certain types of avionics modulation (VOR, ILS, ADF), simultaneous modulation is not possible.

Amplitude modulation (R&S[®]SMAB-K720 option)

For f \geq 100 kHz, attenuator mode: auto, level (PEP) ⁸ = 10 dBm or maximum available output power, whichever is lower. Level = 15 dBm for instruments equipped with R&S[®]SMAB-B32/-B34 ultra high output power option. At high levels, modulation is clipped when the maximum PEP is reached.

Modulation source		internal, external, internal + external	
External coupling		AC, DC	
AM type		linear, exponential	
Linear AM depth			
Setting range	internal modulation source	0 % to 100 %	
	external modulation source	0 %/V to 100 %/V	
Setting resolution		0.01 %(/V)	
AM depth (m) error	f_{mod} = 1 kHz and m < 80 %	< (3 % of reading + 1 %)	
Exponential AM depth			
Setting range	internal modulation source	0 dB to 30 dB	
	external modulation source	0 dB/V to 30 dB/V	
Setting resolution		0.01 dB(/V)	
AM distortion	f _{mod} = 1 kHz		
	m = 30 %	< 1 %	
	m = 80 %	< 2 %	
Modulation frequency response	m = 60 %, coupling: DC/AC, input in	npedance: 50 Ω	
	DC, 10 Hz to 100 kHz	< 3 dB	
Incidental φM at AM	m = 30 %, f _{mod} = 1 kHz, ±peak/2		
	f ≤ 15 GHz	< 0.15 rad	
	15 GHz < f ≤ 20 GHz	< 0.2 rad	
	f > 20 GHz	< 0.2 rad (meas.)	

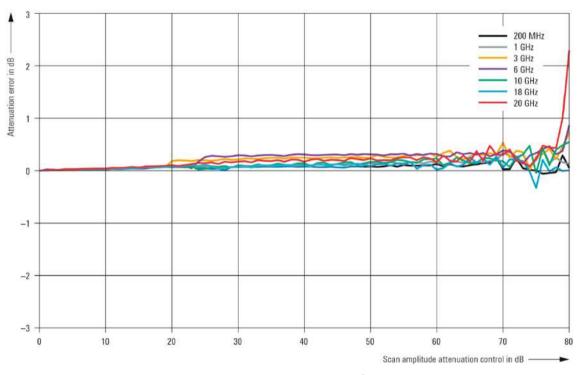
⁸ PEP = peak envelope power.

Scan AM (R&S[®]SMAB-K721 option)

Level (PEP) ⁸ = 10 dBm or maximum available output power, whichever is lower. Level = 15 dBm for instruments equipped with R&S[®]SMAB-B32/-B34/-B35/-B36S/-B37/-B39 ultra high output power option. Scan AM is available for f > 52 MHz.

Prerequisite: R&S[®]SMAB-K720 option must be installed.

Modulation source		internal, external, internal + external	
External coupling		DC	
Scan AM depth			
Setting range	internal modulation source	0 dB to 100 dB	
	external modulation source	0 to 100 dB/V	
Resolution of setting		0.01 dB	
Maximum attenuation		> 60 dB, 70 dB (typ.)	
Attenuation error	level setting characteristic: auto, temperature range from +18 °C to +33 °C		
	specifications are measured for f > 40 GHz		
	0 dB < m ≤ 10 dB	< 0.25 dB	
	10 dB < m ≤ 20 dB	< 1 dB	
	20 dB < m ≤ 40 dB	< 2 dB (typ.)	
	40 dB < m ≤ 50 dB	< 3 dB (typ.)	
	50 dB < m ≤ 60 dB	< 4 dB (typ.)	
Rise/fall time	transition time: 10 % to 90 % (log) for	< 10 µs (meas.)	
	RF amplitude step of 60 dB		



Measured scan AM attenuation error with the R&S®SMAB-K721 option

Frequency bands for frequency modulation, phase modulation and chirped pulses

Multiplier N is used to define FM, ϕ M and chirped pulses specifications within this document.

Multiplier (N) for different frequency	FM mode: low noise,	
ranges	φM mode: low noise	
	f ≤ 8 MHz	1/2
	8 MHz < f ≤ 11.71875 MHz	1/128
	11.71875 MHz < f ≤ 23.4375 MHz	1/64
	23.4375 MHz < f ≤ 46.875 MHz	1/32
	46.875 MHz < f ≤ 93.75 MHz	1/16
	93.75 MHz < f ≤ 187.5 MHz	1/8
	187.5 MHz < f ≤ 375 MHz	1/4
	375 MHz < f ≤ 750 MHz	1/2
	750 MHz < f ≤ 1.5 GHz	1
	1.5 GHz < f ≤ 3 GHz	2
	3 GHz < f ≤ 6 GHz	4
	6 GHz < f ≤ 12 GHz	8
	12 GHz < f ≤ 24 GHz	16
	24 GHz < f ≤ 48 GHz	32
	48 GHz < f ≤ 67 GHz	64
	FM mode: high bandwidth,	
	φM mode: high bandwidth, high deviation	٦,
	chirped pulses	
	f ≤ 350 MHz	1/2
	350 MHz < f ≤ 375 MHz	1/4
	375 MHz < f ≤ 750 MHz	1/2
	750 MHz < f ≤ 1.5 GHz	1
	1.5 GHz < f ≤ 3 GHz	2
	3 GHz < f ≤ 6 GHz	4
	6 GHz < f ≤ 12 GHz	8
	12 GHz < f ≤ 24 GHz	16
	24 GHz < f ≤ 48 GHz	32
	48 GHz < f ≤ 67 GHz	64

Frequency modulation (R&S[®]SMAB-K720 option)

Specifications only valid for main PLL bandwidth normal.

Modulation source		internal, external, internal + external	
External coupling		AC, DC	
FM modes		high bandwidth, low noise	
Maximum deviation	FM mode: high bandwidth	N × 10 MHz	
	FM mode: low noise	N × 100 kHz	
Resolution of setting		< 0.02 % of set deviation or N × 0.1 Hz,	
		whichever is greater, min. 0.01 Hz	
FM deviation error	f_{mod} = 10 kHz, deviation \leq half of max. dev	iation or 10 MHz, whichever is lower	
	source: internal	< (1.5 % of reading + 20 Hz)	
	source: external,	< (2 % of reading + 20 Hz)	
	input impedance: high		
FM distortion	f_{mod} = 10 kHz, deviation = N × 1 MHz	< 0.1 %	
Modulation frequency response	FM mode: high bandwidth, coupling: DC/AC, input impedance: 50 Ω		
	DC, 10 Hz to 100 kHz	< 0.5 dB	
	f > 350 MHz		
	DC, 10 Hz to 10 MHz	< 3 dB	
	f ≤ 350 MHz		
	DC, 10 Hz to 5 MHz	< 3 dB	
	FM mode: low noise, coupling: DC/AC, in	put impedance: 50 Ω	
	DC, 10 Hz to 100 kHz	< 3 dB	
Synchronous AM with FM	FM mode: high bandwidth, 40 kHz deviati	on, f _{mod} = 1 kHz	
	8 MHz < f ≤ 3 GHz	< 0.1 %	
	f > 3 GHz	< 0.2 %	
Carrier frequency offset with FM DC	after FM offset calibration, FM source:	< 0.2 % of set deviation	
(external)	external, input impedance 50 Ω		

Phase modulation (R&S[®]SMAB-K720 option)

Specifications only valid for main PLL bandwidth normal.

Modulation source		internal, external, internal + external		
External coupling		AC, DC		
φM modes		high deviation, high bandwidth, low noise		
Maximum deviation	φM mode: high deviation	N × 20 rad		
	φM mode: high bandwidth	N × 1 rad		
	φM mode: low noise	N × 0.25 rad		
Resolution of setting	φM modes: high deviation, low noise	< 0.02 % of set deviation or N × 20 µrad, whichever is greater, min. 1 µrad		
	φM mode: high bandwidth	< 0.1 % of set deviation,		
		min. N × 20 μrad		
φM deviation error	f _{mod} = 10 kHz, deviation ≤ half of max. de	eviation		
	source: internal	< (1.5 % of reading + 0.003 rad)		
	source: external,	< (2 % of reading + 0.003 rad)		
	input impedance: high			
φM distortion	$f_{mod} = 10 \text{ kHz},$	< 0.2 %, < 0.1 % (typ.)		
	deviation = half of max. deviation			
Modulation frequency response	φM mode: high deviation, coupling: DC/	ϕ M mode: high deviation, coupling: DC/AC, input impedance: 50 Ω		
	deviation ≤ N × 5 rad	< 1 dB		
	DC, 10 Hz to 500 kHz			
	deviation > N × 5 rad	< 1 dB		
	DC, 10 Hz to 10 kHz			
	φM mode: high bandwidth, coupling: DC	C/AC, input impedance: 50 Ω		
	DC, 10 Hz to 100 kHz	< 1 dB		
	f > 350 MHz			
	DC, 10 Hz to 10 MHz	< 3 dB		
	f ≤ 350 MHz			
	DC, 10 Hz to 5 MHz	< 3 dB		
	φM mode: low noise, coupling: DC/AC, i	input impedance: 50 Ω		
	DC, 10 Hz to 100 kHz	< 3 dB		

Pulse modulation (R&S[®]SMAB-K22 option)

Modulation source		external		
	with R&S [®] SMAB-K23 option	external, internal		
On/off ratio		> 80 dB		
Rise/fall time	10 % to 90 % of RF amplitude			
	8 kHz < f ≤ 52 MHz	< 200 ns (meas.)		
	52 MHz < f ≤ 700 MHz	< 10 ns, 5 ns (meas.)		
	700 MHz < f ≤ 50 GHz	< 10 ns, 5 ns (typ.)		
	f > 50 GHz	< 10 ns (meas.)		
Minimum pulse width	f > 700 MHz, 50 % / 50 % of RF amplitude			
	R&S [®] SMAB-B103/-B106/-B112/-B120/ -B131/-B140/-B150/-B167	< 20 ns		
	R&S [®] SMAB-B140N/-B150N/-B167N	30 ns		
Pulse repetition frequency		0 Hz to 25 MHz		
Video feedthrough	level below 10 dBm or maximum specified	level below 10 dBm or maximum specified level, whichever is lower		
	f ≤ 6 GHz	< 10 % of RF		
	f > 6 GHz	< 10 % of RF,		
		< 2 mV (peak-to-peak),		
		whichever is lower		
Pulse overshoot		< 10 %		
Pulse delay	pulse external trigger to RF	pulse external trigger to RF		
	f ≤ 6 GHz	60 ns (meas.)		
	6 GHz < f ≤ 20 GHz	50 ns (meas.)		
	f > 20 GHz	45 ns (meas.)		
Pulse external trigger input				
Input impedance		10 kΩ or 50 Ω (nom.)		
Threshold voltage		0 V to 2.0 V (nom.)		
Input polarity		normal, inverse		

Chirped pulses (R&S[®]SMAB-K725 option)

Prerequisite: R&S[®]SMAB-K22 (high performance pulse modulator), R&S[®]SMAB-K23 (pulse generator) and R&S[®]SMAB-K720 (AM/FM/ ϕ M) options must be installed.

Together with an ideal chirp signal, impairments such as noise, amplitude fluctuations or Doppler drifts can be conveniently added. They are generated using amplitude and frequency modulation on one or more of the additional sources provided by the multifunction generator (R&S[®]SMAB-K24).

Chirp bandwidth multiplier (N) for different	f ≤ 350 MHz	1/2
frequency ranges	350 MHz < f ≤ 375 MHz	1/4
	375 MHz < f ≤ 750 MHz	1/2
	750 MHz < f ≤ 1.5 GHz	1
	1.5 GHz < f ≤ 3 GHz	2
	$3 \text{ GHz} < f \le 6 \text{ GHz}$	4
	6 GHz < f ≤ 12 GHz	8
	12 GHz < f ≤ 24 GHz	16
	24 GHz < f ≤ 48 GHz	32
	48 GHz < f ≤ 67 GHz	64
Modulation source	internal	
Trigger modes	continuous trigger with internal trigger	auto
	source	 externally triggered
		 externally gated
Trigger slope	external trigger signal	positive, negative
Gate polarity	external gate signal	normal, inverse
Input impedance	external trigger/gate signal	50 Ω, 10 kΩ (nom.)
Chirp direction		up, down
Maximum bandwidth		N × 20 MHz
Pulse period setting range		1.0 µs to 100 s
Pulse width setting range		100 ns to 100 s,
		pulse width < (pulse period – 600 ns)
Pulse parameter setting resolution		5 ns
Maximum chirp rate		N × 20 MHz/µs (nom.)

VOR modulation (R&S®SMAB-K25 option)

Attenuator mode AUTO, level (PEP) ⁹ within specified level range. VOR specification valid for carrier frequency range from 108 MHz to 118 MHz.

VOR operating modes	generation of VOR signal	NORM
	30 Hz VAR tone	VAR
	9.96 kHz carrier, unmodulated	subcarrier
	9.96 kHz carrier, modulated	subcarrier + FM
Modulation tones		
Frequency error	30 Hz (VAR, REF)	< (0.001 Hz + relative deviation of
		reference frequency × 30 Hz)
Frequency setting range	30 Hz REF	10 Hz to 60 Hz
	9.96 kHz FM carrier	5 kHz to 15 kHz
	COM/ID tone	0.1 Hz to 20 kHz
Frequency setting resolution		0.1 Hz
FM deviation setting range	9.96 kHz FM carrier	0 Hz to 960 Hz
FM deviation setting resolution	9.96 kHz FM carrier	1 Hz
FM deviation error	9.96 kHz FM carrier at 480 Hz deviation	< 1 Hz
External AM tone	input connector	Ext 1
Modulation depth		
Sum of modulation depths of 30 Hz (V	(AR) signal, 9.96 kHz FM carrier, COM/ID and ext	ternal AM signal must not exceed 100 %.
AM depth setting range		0 % to 100 %
AM depth setting resolution		0.1 %
AM depth error	30 Hz (VAR, REF), 30 % AM depth	< 0.5 % AM depth
	9.96 kHz FM carrier, 30 % AM depth	< 0.5 % AM depth
	COM/ID, tone = 1020 Hz, depth = 10 %	< 0.5 % AM depth
External AM tone	sensitivity	0.01 V/%

⁹ PEP = peak envelope power.

Bearing angle			
Setting range		0° to 360°	
	default setting	0.00°	
Setting resolution		0.01°	
Error		< 0.05°	

ILS modulation (R&S[®]SMAB-K25 option)

Attenuator mode AUTO, level (PEP) ⁹ within specified level range. ILS-LOC specification valid for carrier frequency range from 108 MHz to 118 MHz. ILS-GS specification valid for carrier frequency range from 329 MHz to 335 MHz.

ILS modulation	generation of ILS localizer signal, COM/ID tone possible	ILS-LOC
	generation of ILS glideslope signal	ILS-GS
ILS operating modes	NORM	90 Hz + 150 Hz + COM/ID tone (ILS-LOC)
1 0	90 Hz	suppression of 150 Hz modulation tone
	150 Hz	suppression of 90 Hz modulation tone
ILS modulation tones		
If the frequency of the 90 Hz or 150	Hz tone is varied, the other tone is automatically ch	anged in proportion.
Frequency error		< (0.02 Hz + relative deviation of
		reference frequency × ILS tone frequency)
Frequency setting range	90 Hz tone	60 Hz to 120 Hz
	150 Hz tone	100 Hz to 200 Hz
	COM/ID tone	0.1 Hz to 20 kHz
Frequency setting resolution	90 Hz tone	0.3 Hz
	150 Hz tone	0.5 Hz
	COM/ID tone	0.1 Hz
External AM tone	input connector	Ext 1
Modulation depth		
Sum of modulation depths of 90 Hz,	150 Hz, COM/ID and external AM signal must not	exceed 100 %.
Setting range	SDM of 90 Hz, 150 Hz, COM/ID tone	0 % to 100 %
	ILS-LOC default setting	40 %
	ILS-GS default setting	80 %
Setting resolution	SDM and COM/ID depth	0.1 %
AM depth error	SDM = 40 %	< 0.8 % AM depth
	SDM = 80 %	< 1.6 % AM depth
	COM/ID, tone = 1020 Hz, depth = 10 %	< 0.5 % AM depth
External AM tone	sensitivity	0.01 V/%
Difference in depth of modulation	(DDM)	
Setting range		0 to ±SDM
Setting resolution		0.0001
Error		< 0.0003 + 2 % of set DDM
ILS phase	· · · · · · · · · · · · · · · · · · ·	
Setting range		0° to 120°
Setting range		
Setting resolution		0.01°

Marker beacon (MKR BCN) (R&S®SMAB-K25 option)

Attenuator mode AUTO, level (PEP) within specified level range. MKR-BCN specification valid for carrier frequency range from 74 MHz to 76 MHz.

Marker beacon modulation tones		
Frequency error		< (0.001 Hz + relative deviation of
		reference frequency × marker frequency)
Marker frequencies		400 Hz, 1300 Hz and 3000 Hz
COM/ID tone frequency setting range		0.1 Hz to 20 kHz
COM/ID tone frequency setting resolution		0.1 Hz
Marker beacon modulation depth		
Sum of modulation depths of marker tone a	and COM/ID signal must not exceed 10	00 %.
AM depth setting range		0 % to 100 %
	marker tone default setting	95 %
AM depth setting resolution		0.1 %
AM depth error	marker tone	< 4 % AM depth
	COM/ID, tone = 1020 Hz	< 0.5 % AM depth

ADF mode (R&S[®]SMAB-K25 option)

The ADF mode provides a carrier frequency of 190 kHz with 30 % AM depth at 1 kHz modulation rate.

Frequency error	ADF tone	< (0.001 Hz + relative deviation of	
		reference frequency × ADF frequency)	
ADF frequency setting range		0.1 Hz to 20 kHz	
ADF setting resolution		0.1 Hz	
AM depth setting range		0 % to 100 %	
AM depth setting resolution		0.1 %	
	ADF tone default setting	30 %	

Sources for analog modulation

Modulation sources for AM, Scan AM, FM and ϕ M

3 different modulation sources are available as modulation signals:

- Internal modulation generator (standard feature)
- Multifunction generator (R&S[®]SMAB-K24 option)
- External modulation signals

The AM or Scan AM and FM or ϕ M modulation sources 1 and 2 can be selected individually or simultaneously. The LF generators 1 and 2 and the noise generator are part of the multifunction generator (R&S[®]SMAB-K24 option).

AM or S	Scan AM	FM or	·φM
Modulation source 1 ¹⁰	Modulation source 2 ¹⁰	Modulation source 1 ¹⁰	Modulation source 2 ¹⁰
LF generator 1	LF generator 1	LF generator 1	LF generator 1
LF generator 2	LF generator 2	LF generator 2	LF generator 2
Noise	Noise	Noise	Noise
External 1	External 1	External 1	External 1
External 2	External 2	External 2	External 2

Internal modulation generator

Signal types		sine
Frequency setting range		0.1 Hz to 1 MHz
Frequency setting resolution		0.01 Hz
Frequency error		< (0.001 Hz + relative deviation of
		reference frequency × modulation
		frequency)
Frequency response	up to 1 MHz	< 0.3 dB
Distortion	f < 100 kHz,	< 0.1 %
	at $R_L \ge 50 \Omega$, level (V _{EMF}): < 1 V	

Multifunction generator (R&S[®]SMAB-K24 option)

Signal types	LF generator 1	sine, square, pulse, triangle, trapezoid
	LF generator 2	sine, square, pulse, triangle, trapezoid
	noise generator	Gaussian, uniform
	(noise amplitude distribution)	
Frequency range	sine	0.1 Hz to 10 MHz
	square	0.1 Hz to 1 MHz
	pulse, triangle, trapezoid	0.01 Hz to 1 MHz (displayed value)
	noise bandwidth	100 kHz to 10 MHz
Resolution of setting	sine, square	0.01 Hz
-	pulse, triangle, trapezoid	10 ns
	noise bandwidth	100 kHz
Frequency error	sine	< (0.001 Hz + relative deviation of
		reference frequency × modulation
		frequency)
Frequency response	sine, up to 1 MHz	< 0.3 dB
	sine, up to 10 MHz	< 1 dB
Distortion	f < 100 kHz,	< 0.1 %
	at $R_L \ge 50 \Omega$, level (V _{EMF}): 1 V	

¹⁰ One out of five sources can be selected.

LF frequency sweep

Operating mode		digital sweep in discrete steps
Trigger modes	execute sweep continuously with internal	auto
	trigger source	
	execute one full sweep	single
	execute one step	step
	sweep start and stop controlled by	start/stop
	external trigger signal	
Trigger source		external trigger signal (INST TRIG
		at rear), rotary knob, touch panel,
		remote control
Sweep range		full frequency range
Sweep shape		sawtooth, triangle
Step size setting resolution	linear	0.1 Hz
	logarithmic	0.01 %
Dwell time setting range		3 ms to 100 s
Dwell time setting resolution		0.1 ms

LF output

Monitoring of resulting modulation signal for		ΑΜ, FM, φΜ
Source		LF generator 1, LF generator 2, noise
		generator, external 1, external 2
Output voltage	V _{peak} at LF connector, open-circuit voltage EMF	
Setting range		1 mV to 4 V
Setting resolution		1 mV
Setting error	$f = 1 \text{ kHz}, R_L > 50 \text{ k}\Omega$	< (1 % of reading + 1 mV)
Output impedance		50 Ω (nom.)

Pulse generator (R&S[®]SMAB-K23 option)

Pulse modes		single pulse, double pulse
Trigger modes	free run, internally triggered	auto
		external trigger
		external gate
Pulse period		
Setting range		20 ns to 100 s
Setting resolution		5 ns
Pulse width	pulse widths of double pulses can b	e set independently
Setting range		5 ns to 100 s
Setting resolution		5 ns
Pulse delay		
Setting range		0 s to 100 s
Setting resolution		5 ns
Double-pulse spacing		
Setting range		10 ns to 100 s
Setting resolution		5 ns
External trigger		
Delay	trigger to video output	40 ns (nom.)
Jitter		< 5 ns (nom.)

Pulse train (R&S[®]SMAB-K27 option)

The R&S[®]SMAB-K27 option extends the functionality of the pulse generator (R&S[®]SMAB-K23 option). With this option, pulses and sequences of pulses can be user-defined in order to generate jittered or staggered pulse scenarios widely used in radar applications.

Prerequisite: R&S[®]SMAB-K23 option must be installed.

Pulse mode	user-settable pulse width, pulse spacing and pulse sequences	train
Trigger modes	free run, internally triggered	auto
		external trigger
Number of bursts		1 to 2047
Number of identical pulses per burst		1 to 65535
Pulse on time setting range		0 ns to 5 ms
Pulse off time setting range		5 ns to 5 ms
Pulse on and off time setting resolution		5 ns

Pulse generator outputs

SYNC output	output of a synchronizing pulse at	output of a synchronizing pulse at pulse start or start of pulse sequence	
Connector type	PULSE SYNC output	BNC female	
SYNC output level		digital signal with 0 V/4.2 V (nom.) with no load, source resistance: $R_s = 50 \Omega$ (nom.),	
		load impedance: $R_L \ge 50 \Omega$	
SYNC pulse width		5 ns (nom.)	
VIDEO output	output of pulse generator signal		
Connector type	PULSE VIDEO output	BNC female	
VIDEO output level		digital signal with 0 V/4.2 V (nom.) with no	
		load, source resistance: $R_s = 50 \Omega$ (nom.),	
		load impedance: $R_{L} \ge 50 \Omega$	

Additional performance options

Differential clock synthesizer (R&S®SMAB-B29 option)

The R&S[®]SMAB-B29 option provides a differential or single-ended clock signal with selectable waveform and DC offset up to 3 GHz or up to 6 GHz with the R&S[®]SMAB-K722 option.

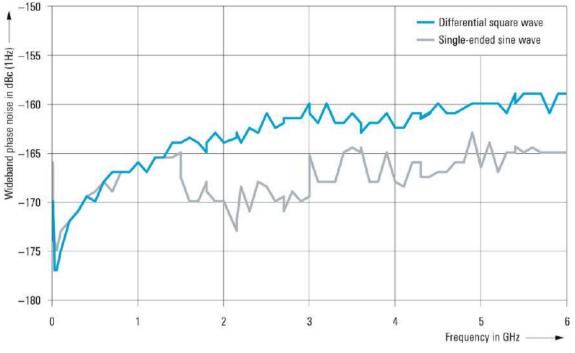
The R&S[®]SMAB-K722 option is not available for instruments equipped with the 3 GHz R&S[®]SMAB-B103 RF frequency option. The frequency of the clock synthesizer (R&S[®]SMAB-B29 option) can be set independently of the RF frequency of the R&S[®]SMAB100A.

Specifications above 3 GHz are only valid for instruments equipped with the R&S®SMAB-K722 option.

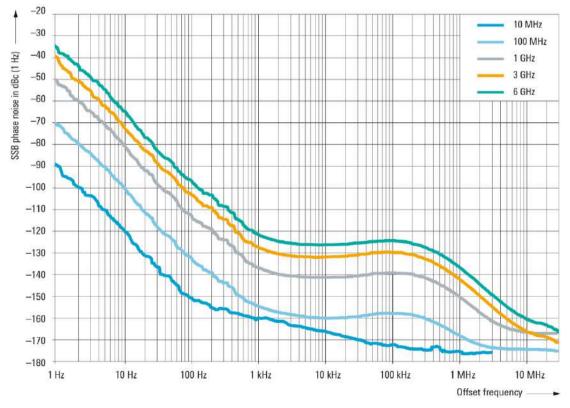
Output types		differential square wave,
Output types		differential sine wave,
		single-ended sine wave,
		differential CMOS
Frequency		
Frequency range	differential square wave,	100 kHz to 3 GHz
	single-ended sine wave	
	differential sine wave	10 MHz to 3 GHz
	with R&S [®] SMAB-K722 option	10 MHz to 6 GHz
	differential square wave, single-ended	100 kHz to 6 GHz
	sine wave	
	differential sine wave	10 MHz to 6 GHz
	CMOS output	100 kHz to 200 MHz
Resolution of setting		0.001 Hz
Resolution of synthesis	f = 1 GHz	0.053 nHz (nom.)
Frequency setting time	to within < 1 × 10^{-7} for f > 10 MHz,	< 1.5 ms
	with GUI update stopped	
	after IEC/IEEE bus delimiter with	
	R&S [®] SMAB-B86 option	
Level		1
Level setting range	sine wave, differential and single-ended	-24 dBm to 20 dBm
<u> </u>	differential square wave	fixed
	differential CMOS	0.8 V to 2.7 V
Output connectors		
Connector type	CLK SYN, CLK SYN_N outputs	SMA female
	with R&S [®] SMAB-B93 option (3 HU)	front panel
	with R&S [®] SMAB-B92 option (2 HU) or	rear panel
	with R&S [®] SMAB-B93 option (3 HU) and	
	R&S [®] SMAB-B80/-B81/-B82 rear panel	
	connector option	
Reverse power		
Reverse power (from 50 Ω source)	maximum permissible RF power	0.05 W
Maximum permissible DC voltage	sine wave and square wave, DC offset	±5 V
	disabled	
	any output type with DC offset enabled	0 V (short-circuit-proof)
	differential CMOS	0 V (short-circuit-proof)
DC offset		1
Setting range	not available in CMOS mode	–5 V to +5 V
Setting resolution		1 mV
DC offset source impedance		50 Ω (nom.)
Spectral purity		
Nonharmonics	offset > 10 kHz from carrier, level = 10 dBm	
	f ≤ 10 MHz	< -90 dBc
	10 MHz < f ≤ 750 MHz	< -96 dBc
	750 MHz < f ≤ 1.5 GHz	< -92 dBc
	1.5 GHz < f ≤ 3 GHz	<86 dBc
	3 GHz < f ≤ 6 GHz	< –80 dBc
	instruments equipped with R&S [®] SMAB-B70	
	f ≤ 1.5 GHz	< –100 dBc
	1.5 GHz < f ≤ 3 GHz	< -94 dBc
	3 GHz < f ≤ 6 GHz	<88 dBc

Subharmonics ¹¹	level = 10 dBm, sine wave			
	f ≤ 3 GHz	< –94 dBc		
	3 GHz < f ≤ 6 GHz	<88 dBc		
Wideband noise	maximum output level, sine wave, carrier measurement bandwidth: 1 Hz	maximum output level, sine wave, carrier offset: 10 MHz,		
	carrier offset: 10 MHz or 10 % of carrie	er frequency, whichever is lower		
	f ≤ 8 MHz	< -150 dBc		
	8 MHz < f ≤ 1.5 GHz	< -155 dBc		
	1.5 GHz < f ≤ 3 GHz	< –153 dBc		
	carrier offset: 30 MHz			
	3 GHz < f ≤ 6.0 GHz	< –150 dBc		
	instruments equipped with R&S [®] SMAB-B			
	carrier offset: 10 MHz or 10 % of carrie			
	f ≤ 8 MHz	< -150 dBc		
	8 MHz < f ≤ 1.5 GHz	< -157 dBc		
	1.5 GHz < f ≤ 3 GHz	< –155 dBc		
	carrier offset: 30 MHz			
	3 GHz < f ≤ 6.0 GHz	< –155 dBc		
SSB phase noise	single-ended and differential sine wave o			
	carrier offset: 20 kHz, measurement bandwidth: 1 Hz			
	f = 10 MHz	< -163 dBc, -168 dBc (typ.)		
	f = 100 MHz	< -155 dBc, -162 dBc (typ.)		
	f = 1 GHz	< -135 dBc, -142 dBc (typ.)		
	f = 2 GHz	< -129 dBc, -136 dBc (typ.)		
	f = 3 GHz	< -125 dBc, -133 dBc (typ.)		
	f = 4 GHz	< -123 dBc, -130 dBc (typ.)		
	f = 6 GHz	< -119 dBc, -126 dBc (typ.)		
	instruments equipped with R&S [®] SMAB-B709/-B710(N)/-B711(N)			
	f = 10 MHz	< -163 dBc, -168 dBc (typ.)		
	f = 100 MHz	< -158 dBc, -164 dBc (typ.)		
	f = 1 GHz	< -141 dBc, -145 dBc (typ.)		
	f = 2 GHz	< -135 dBc, -139 dBc (typ.)		
	f = 3 GHz	< -131 dBc, -135 dBc (typ.)		
	f = 4 GHz	< -129 dBc, -133 dBc (typ.)		
	f = 6 GHz	< -125 dBc, -130 dBc (typ.)		
RMS jitter	single-ended and differential sine wave o			
-	f = 155 MHz, BW = 100 Hz to 1.5 MHz	18.3 fs (meas.)		
	f = 622 MHz, BW = 1 kHz to 5 MHz	18.0 fs (meas.)		
	f = 1 GHz, BW = 1 Hz to 10 MHz	558 fs (meas.)		
	f = 2.488 GHz, BW = 5 kHz to 20 MHz	18.0 fs (meas.)		
With R&S [®] SMAB-B709 option	f = 155 MHz, BW = 100 Hz to 1.5 MHz	13.6 fs (meas.)		
•	f = 622 MHz, BW = 1 kHz to 5 MHz	13.7 fs (meas.)		
	f = 1 GHz, BW = 1 Hz to 10 MHz	129 fs (meas.)		
	f = 2.488 GHz, BW = 5 kHz to 20 MHz	13.6 fs (meas.)		
With R&S [®] SMAB-B710(N) or	f = 155 MHz, BW = 100 Hz to 1.5 MHz	13.6 fs (meas.)		
R&S [®] SMAB-B711(N) option	f = 622 MHz, BW = 1 kHz to 5 MHz	13.7 fs (meas.)		
· · ·	f = 1 GHz, BW = 1 Hz to 10 MHz	21.6 fs (meas.)		
	f = 2.488 GHz, BW = 5 kHz to 20 MHz	13.7 fs (meas.)		

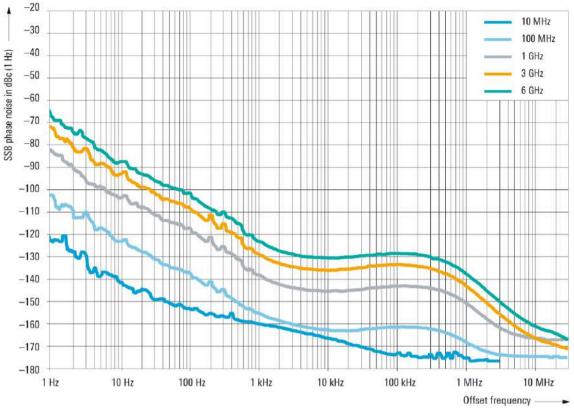
¹¹ Specifications are not valid for subharmonics beyond "specified frequency range".



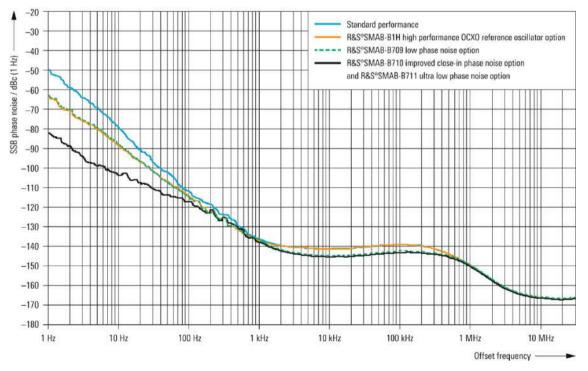
Measured wideband noise of clock synthesizer output at maximum output power versus carrier frequency with the R&S[®]SMAB-B29 and R&S[®]SMAB-K722 options. Measured with the R&S[®]FSWP phase noise analyzer



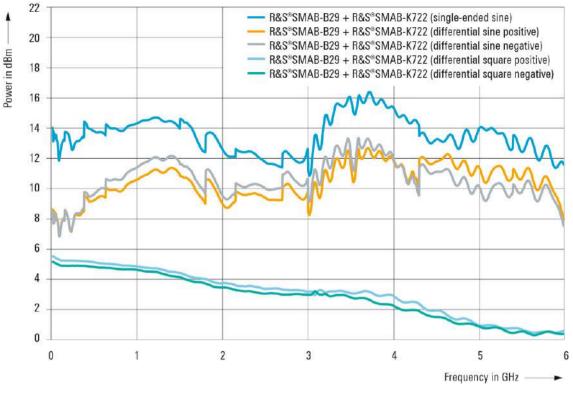
Measured SSB phase noise of clock synthesizer (standard performance) with the R&S[®]SMAB-B29 and R&S[®]SMAB-K722 options



Measured SSB phase noise of clock synthesizer with the R&S[®]SMAB-B29, R&S[®]SMAB-B711(N) and R&S[®]SMAB-K722 options



Measured SSB phase noise of clock synthesizer at f = 1 GHz, standard performance versus the R&S[®]SMAB-B1H, R&S[®]SMAB-B709, R&S[®]SMAB-B710(N) and R&S[®]SMAB-B711(N) options



Measured maximum available output power versus frequency for the R&S[®]SMAB-B29 and R&S[®]SMAB-K722 options

R&S®NRP-Z power analysis (R&S®SMAB-K28 option)

Overview of supported power sensor and functionalities

Latest power sensor firmware version is recommended.

Power sensor	Power versus frequency and power versus power	Power versus time	Pulse data measurement
R&S [®] NRP-Z81/-Z85/-Z86	•	•	•

• = supported, - = not supported.

Modes		power versus frequency
		 power versus power
		 power versus time (trace mode)
General settings		
Number of points per sweep (= steps)		10 to 1000
Frequency range	depending on R&S [®] NRP-Zxx power	full frequency range of signal generator or
	sensor and R&S [®] SMA100B frequency	power sensor (whichever is lower);
	option	support of frequency-converting DUTs
Y-axis setting range		-200 dBm to +100 dBm
Uncertainty of measured power	determined by power sensor used and	see R&S [®] NRP data sheet
	timing mode (noise)	(PD 3607.0852.22)
Sweep mode		single
		continuous
Number of traces	used for sensor data or as reference trace	4
Number of markers		4
Trace data export	supported file formats	JPG, BMP, XPM, PNG, CSV
Resolution of saved graphic file	for JPG, BMP, XPM and PNG file format	800 x 480 pixel (size of screen)

Power versus frequency mode			
Spacing		linear, logarithmic	
Timing mode		fast, normal	
Sweep time	depends on timing mode, number of steps and power sensor	set automatically	
	e.g. R&S [®] NRP-Z81 timing mode FAST, 200 steps	approx. 2.5 s	
Power versus power mode			
Spacing		dB steps	
Timing mode		fast, normal	
Sweep time	depends on timing mode, steps and power sensor	set automatically	
	e.g. R&S [®] NRP-Z81 timing mode FAST, 200 steps	approx. 2.5 s	
Power versus time mode (trace mode	9 <i>i</i> 1	1	
Spacing	/	linear	
Sweep time	R&S [®] NRP-Z81/-Z85/-Z86		
	setting range	100 ns to 1 s	
	resolution	12.5 ns	
	(sweep time/steps) ≥ 12.5 ns		
	resolution	2 ns	
	(sweep time/steps) < 12.5 ns, periodic signals,		
	trigger mode internally triggered		
Trace offset	with reference to trigger event	positive, negative	
Average		1 to 1024	
Trigger modes	internally triggered	auto, free run, internal	
	externally triggered, R&S [®] NRP-Z3 required	external	
Trigger level setting range	depends on power sensor used	see R&S [®] NRP data sheet (PD 3607.0852.22)	
Trigger hysteresis setting range		0 dB to 10 dB	
Trigger dropout time setting range		0 ns to 10 s	
Available measurements in time mod	e		
Gate function			
Number of gates	user-selectable	2	
Power measurements		peak power, average power	
Pulse data measurement, only with R&S	[®] NRP-Z81/-Z85/-Z86		
Timing measurements		duty cycle, pulse width, pulse period, pulse off time, rise time, pulse start time, overshoot, fall time, pulse stop time	
Power measurements		peak power, average power, minimal power, top power, base power, distal power, mesial power, proximal power	
Setting range for distal, mesial and proximal threshold	voltage or power-related	0 % to 100 %	

Remote control

Interfaces/systems	standard	Ethernet/LAN 10/100/1000BASE-T
	with R&S [®] SMAB-B86 option	IEC 60625 (GPIB IEEE-488.2),
		USB 2.0 (according to VISA USB-TMC),
		serial (RS-232) ¹²
Command set		SCPI 1999.5 or compatible command sets
Compatible command sets	These command sets can be selected in	Hewlett Packard
	order to emulate another instrument.	 HP 8340, HP 8341
	A subset of common commands is	• HP 8360
	supported.	 HP 83620, HP 83622, HP 83623,
	For each emulated instrument, the *IDN?	HP 83624
	and *OPT? strings can be configured to	 HP 83630, HP 83640, HP 83650
	• •	
	meet the specific requirements. This is	• HP 8373
	particularly useful for the Aeroflex/IFR/Marconi instruments since	• HP 83711, HP 83712
		• HP 83731, HP 83732
	the manufacturer ID changed over time	• HP 8642, HP 8643, HP 8644, HP 8645
	and for the Hewlett-Packard/Agilent	• HP 8647, HP 8648
	instruments to adapt to a specific suffix	 HP 8656, HP 8657
	and configuration.	 HP 8662, HP 8663, HP 8664, HP 8665
		• HP 8673
		Agilent/Keysight Technologies
		 E4421, E4422, E4428
		 E4421, E4422, E4428 E8257, E8663
		N5161, N5181, N5183
		• N5171, N5173
		Aeroflex (IFR/Marconi)
		• 2023, 2024
		• 2030, 2031, 2032
		• 2040, 2041, 2042
		Anritsu
		• 68017, 68037
		Panasonic
		• VP-8303A
		Racal Dana
		• 3102, 9087
		Rohde & Schwarz
		• R&S [®] SMA100A
		 R&S[®]SME02/03/06
		 R&S[®]SMF100A
		R&S [®] SMG/SMH
		 R&S[®]SMGU/SMHU
		 R&S[®]SML01/02/03
		• R&S [®] SMP02/03/04
		• R&S [®] SMR20/27/30/40
		• R&S [®] SMT02/03/06
		• R&S [®] SMY01/02
IEC/IEEE bus address		0 to 30
Ethernet/LAN protocols and services		 VISA VXI-11 (remote control)
		Telnet/RawEthernet (remote control)
		 VNC (remote operation with web
		browser)
		FTP (file transfer protocol)
		SMB (mapping parts of the instrument
		to a host file system)
Ethernet/LAN addressing		to a host file system) DHCP, static;
Ethernet/LAN addressing		. ,
Ethernet/LAN addressing		DHCP, static;

 $^{^{\}rm 12}\,$ Requires the R&S®TS-USB1 serial adapter (recommended extra).

Connectors

All digital inputs and outputs are CMOS 3.3 V unless otherwise noted. The input damage level is below -0.5 V or above +5 V.

Front or rear panel connectors

These connectors are located either on the front or the rear panel of the instrument, depending on the option configuration.

Model with 2 HU (equipped with the R&S[®]SMAB-B92 option): RF 50 Ω, USB, SENSOR, SD card on the front panel, all others on the rear panel.

Model with 3 HU (equipped with the R&S[®]SMAB-B93 option): all connectors on front panel.

Model with 2 or 3 HU and equipped with an R&S[®]SMAB-B80/-B81/-B82 rear panel connector option: all except USB on the rear panel.

RF 50 Ω	RF output		
	R&S [®] SMAB-B103/-B106	N female	
	R&S®SMAB-B112/-B120/-B131/	test port adapter, PC 2.92 mm female	
	-B140/-B140N	(interchangeable port connector system)	
	R&S®SMAB-B150/-B167/-B150N/	1.85 mm female	
	-B167N	(instrument equipped with	
		interchangeable 1.85 mm female/female	
		wear and tear adapter, factory calibration	
		plane is at the output of the adapter)	
LF	LF generator output	BNC female	
Ext 1, Ext 2	input for external analog modulation	BNC female	
	(AM, FM, φM, Scan AM)		
Input impedance		100 kΩ; 600 Ω or 50 Ω (nom.)	
Input sensitivity	AM, FM, φM: peak value for set deviation	1 V (nom.)	
Input voltage range	Scan AM		
	Ext 1	-6 V to 0 V	
	Ext 2	-1 V to 0 V	
Input damage voltage	50 Ω input impedance	< -7 V or > +7 V	
	600 Ω and 100 kΩ input impedance	< -10 V or > +10 V	
Pulse Ext	input for external pulse modulation,	BNC female/digital signal	
	external trigger input for pulse generator,	5 5	
	external gate input for pulse generator		
Input impedance	selectable	10 kΩ or 50 Ω (nom.)	
Input voltage	TTL, CMOS compatible		
	threshold voltage	0 V to 2.0 V (nom.)	
Input damage voltage		< -0.5 V or > +5 V	
Input polarity	selectable	normal, inverse	
Pulse Video	pulse generator output,	BNC female/digital signal	
	video output for external pulse modulation		
Pulse Sync	synchronizing output for pulse generator	BNC female/digital signal	
Sensor	connector for R&S [®] NRP power sensor	6-pin ODU mini-snap series B,	
		mechanically compatible with 8-pin ODU	
		mini-snap series B	
USB	USB 2.0 connector for external USB	USB type A	
	devices such as mouse, keyboard,		
	R&S [®] NRP power sensors (with		
	R&S [®] NRP-Z4 adapter cable), memory		
	stick for software update and data		
	exchange or USB serial adapter for		
	RS-232 remote control		
SD	with R&S [®] SMAB-B85 option	SD card slot	
	for removable mass storage		
Clk Syn	clock synthesizer output	SMA female	
Clk Syn_N	clock synthesizer inverted output	SMA female	

Rear panel connectors

Ref In	external reference frequency input	BNC female	
Input damage level		> 20 dBm	
Ref Out	reference frequency output	BNC female	
Ref In 1 GHz	external 1 GHz reference frequency input	SMA female	
Input damage level		> 20 dBm	
Ref Out 1 GHz	ultra low noise 1 GHz reference frequency output	SMA female	
Ext Tune	input for electronic tuning of internal reference frequency	BNC female	
Inst Trig	trigger input for sweep and list mode	BNC female/digital signal	
Signal Valid	output for triggering external devices, high state indicates that the instrument has settled to its final value	BNC female/digital signal	
V/GHz X-Axis	with R&S [®] SMAB-B28 option, delivers voltage level proportional to absolute sweep frequency or sweep progress	BNC female	
Load impedance		≥ 1 kΩ	
Z-Axis	with R&S [®] SMAB-B28 option, delivers pulses with different levels to indicate frequency markers and blanking signals	BNC female	
Load impedance		≥ 10 kΩ	
Stop	with R&S [®] SMAB-B28 option, bidirectional signal to indicate halted sweep or to stop sweep by external device	BNC female/digital signal	
Input polarity		low active	
Marker User 1	with R&S [®] SMAB-B28 option, pulse output to mark selected frequencies	BNC female/digital signal	
Input polarity	selectable	normal, inverse	
LAN	provides remote control functionality and other services, see section "Remote control"	RJ-45	
USB	USB 2.0 connector for external USB devices such as mouse, keyboard, R&S®NRP power sensors (with adapter cable R&S®NRP-Z4), memory stick for software update and data exchange or USB serial adapter for RS-232 remote control	USB type A	
USB In	with R&S [®] SMAB-B86 option, USB 2.0, remote control of instrument	USB type micro-B	
IEEE-488	with R&S [®] SMAB-B86 option, remote control of instrument via GPIB	24-pin Amphenol series 57 female	

General data

Power rating		
Rated voltage		100 V to 240 V AC (± 10 %)
Rated frequency		50 Hz to 60 Hz (± 5 %), 400 Hz (± 5 %)
Rated current	model with 2 HU	3.5 A to 1.6 A (50 Hz to 60 Hz),
	(R&S [®] SMAB-B92 option)	3.5 A to 2.9 A (400 Hz)
	model with 3 HU (R&S [®] SMAB-B93 option)	7.3 A to 4.6 A (50 Hz to 60 Hz/400 Hz)
Rated power	model with 2 HU (R&S [®] SMAB-B92 option), when fully equipped	300 W (meas.)
	model with 3 HU (R&S [®] SMAB-B93 option), when fully equipped	380 W (meas.)
Power factor correction		in line with EN 61000-3-2
Product conformity		
Electromagnetic compatibility	EU: in line with EMC Directive 2004/108/EC	 applied harmonized standards: EN 61326-1 (industrial environment) EN 61326-2-1 EN 55011 class A EN 61000-3-2 EN 61000-3-3
Electrical safety	EU: in line with Low Voltage Directive	applied harmonized standard:
	2006/95/EC	EN 61010-1
	USA	UL 61010-1
	Canada	CAN/CSA-C22.2 No. 61010-1
International safety approvals	VDE – Association for Electrical,	GS mark 40045930
	Electronic and Information Technologies	
	CSA – Canadian Standards Association	CSA _{UL} mark 70108101
Mechanical resistance		
Vibration	sinusoidal	5 Hz to 55 Hz, 0.15 mm amplitude const., 55 Hz to 150 Hz, 0.5 g const., in line with EN 60068-2-6
	random	10 Hz to 300 Hz, 1.2 g (RMS) acceleration, in line with EN 60068-2-64
Shock		40 g shock spectrum, in line with MIL-STD-810E, method 516.4, procedure I
Environmental conditions	1	
Temperature range	operating	0 °C to +55 °C
, ,	operating, with R&S [®] SMAB-B36S option	0 °C to +45 °C
	storage	-40 °C to +71 °C,
	Ŭ	temperature gradient < 5 K/h
Damp heat		+40 °C, 90 % rel. humidity, steady state, in line with EN 60068-2-78
Altitude	operating, linear derating of max. ambient temperature to +45 °C starting at altitude = 3000 m	4600 m (15000 ft)
	transport	4600 m (15000 ft)

Weight and dimensions Dimensions (W x H x D)	model with 2 HU	460 mm x 107 mm x 503 mm
	(R&S [®] SMAB-B92 option)	(18.1 in × 4.21 in × 19.8 in)
	without front handles and feet	445 mm × 89 mm × 485 mm
		(17.5 in × 3.5 in × 19.1 in)
	model with 3 HU	460 mm × 151 mm × 503 mm
	(R&S [®] SMAB-B93 option)	(18.1 in × 5.95 in × 19.8 in)
	without front handles and feet	445 mm × 133 mm × 485 mm
		(17.5 in × 5.24 in × 19.1 in)
Weight	model with 2 HU	14.4 kg (31.7 lb)
	(R&S [®] SMAB-B92 option),	
	when fully equipped	
	model with 3 HU	18.0 kg (39.6 lb)
	(R&S [®] SMAB-B93 option),	
	when fully equipped	
Display		
Resolution		800 × 480 pixel
Size	2 HU model	5" touch display
	3 HU model	7" touch display
Calibration interval		
Recommended calibration interval	operation 40 h/week in the full range of	3 years
	the specified environmental conditions	

Ordering information

R&S[®]SMAB-Bxxx = hardware option

R&S[®]SMAB-Kxxx = software/keycode option

Designation	Туре	Order No.
Signal generator ¹³	R&S [®] SMA100B	1419.8888.02
including power cable and quick start guide		
Options		
Frequency options		
8 kHz to 3 GHz	R&S [®] SMAB-B103	1420.8488.02
8 kHz to 6 GHz	R&S [®] SMAB-B106	1420.8588.02
8 kHz to 12.75 GHz	R&S [®] SMAB-B112	1420.8688.02
8 kHz to 20 GHz	R&S [®] SMAB-B120	1420.8788.02
8 kHz to 31.8 GHz	R&S [®] SMAB-B131	1420.8888.02
8 kHz to 40 GHz	R&S [®] SMAB-B140	1420.8988.02
8 kHz to 40 GHz	R&S [®] SMAB-B140N	1420.8965.02
8 kHz to 50 GHz	R&S [®] SMAB-B150	1420.9049.02
8 kHz to 50 GHz	R&S [®] SMAB-B150N	1420.9026.02
8 kHz to 67 GHz	R&S [®] SMAB-B167	1420.9149.02
8 kHz to 67 GHz	R&S [®] SMAB-B167N	1420.9126.02
Platform height options		
2 HU with 5" touch display	R&S [®] SMAB-B92	1420.8288.04
3 HU with 7" touch display	R&S [®] SMAB-B93	1420.8388.04
Phase noise performance and reference oscillator options		,
High performance OCXO reference oscillator ¹⁴	R&S [®] SMAB-B1H	1420.8188.02
Low phase noise ¹⁴	R&S [®] SMAB-B709	1420.9849.02
Improved close-in phase noise performance for R&S [®] SMAB-B106/-B112/-B120/-B131/-B140/-B150/-B167 ¹⁴	R&S [®] SMAB-B710	1420.8007.02
Improved close-in phase noise performance for R&S [®] SMAB-B103 ¹⁴	R&S [®] SMAB-B710N	1420.8107.02
Ultra low phase noise for R&S [®] SMAB-B106/-B112/-B120/-B131/-B140/-B150/-B167 ¹⁴	R&S [®] SMAB-B711	1420.8020.02
Ultra low phase noise for R&S [®] SMAB-B103 ¹⁴	R&S [®] SMAB-B711N	1420.8120.02
100 MHz, 1 GHz ultra low noise reference input/output	R&S [®] SMAB-K703	1420.9761.02
Flexible reference input from 1 MHz to 100 MHz	R&S [®] SMAB-K704	1420.9778.02
Output power options		
High output power 3 GHz/6 GHz	R&S [®] SMAB-K31	1420.7100.02
Ultra high output power 3 GHz/6 GHz ¹⁵	R&S [®] SMAB-B32	1420.7200.02
High output power 12.75 GHz/20 GHz	R&S [®] SMAB-K33	1420.7300.02
Ultra high output power 12.75 GHz/20 GHz ¹⁶	R&S [®] SMAB-B34	1420.7400.02
High output power 31.8 GHz/40 GHz ¹⁷	R&S [®] SMAB-B35	1420.7500.02
Ultra high output power 31.8 GHz/40 GHz ¹⁸	R&S [®] SMAB-K36	1420.9178.02
Super ultra high output power 31.8 GHz/40 GHz ¹⁹	R&S [®] SMAB-B36S	1420.9190.02
High output power 50 GHz ¹⁷	R&S®SMAB-B37	1420.7700.02
Ultra high output power 50 GHz ²⁰	R&S [®] SMAB-K38	1420.9255.02
High output power 67 GHz ¹⁷	R&S [®] SMAB-B39	1420.7900.02
Ultra high output power 67 GHz ²¹	R&S [®] SMAB-K40	1420.9278.02

¹³ The base unit can only be ordered with an R&S[®]SMAB-B1xx frequency option and an R&S[®]SMAB-B92 or R&S[®]SMAB-B93 platform height option.

¹⁴ Only one of the following six options can be installed: R&S[®]SMAB-B1H, R&S[®]SMAB-B709, R&S[®]SMAB-B710, R&S[®]SMAB-B710N, R&S[®]SMAB-B711N, R&S[®]SMAB-B711N.

¹⁵ R&S[®]SMAB-B32 can only be ordered in combination with R&S[®]SMAB-K31.

¹⁶ R&S[®]SMAB-B34 can only be ordered in combination with R&S[®]SMAB-K33.

¹⁷ Requires R&S[®]SMAB-B93 3 HU option.

¹⁸ R&S[®]SMAB-K36 can only be ordered in combination with R&S[®]SMAB-B35.

¹⁹ R&S[®]SMAB-B36S can only be ordered in combination with R&S[®]SMAB-B35 and R&S[®]SMAB-K36.

²⁰ R&S[®]SMAB-K38 can only be ordered in combination with R&S[®]SMAB-B37.

²¹ R&S[®]SMAB-K40 can only be ordered in combination with R&S[®]SMAB-B39.

Designation	Туре	Order No.
Analog modulation options		
High performance pulse modulator	R&S [®] SMAB-K22	1420.9710.02
Pulse generator	R&S [®] SMAB-K23	1420.9726.02
Multifunction generator	R&S [®] SMAB-K24	1420.9732.02
VOR/ILS	R&S [®] SMAB-K25	1420.9855.02
Pulse train 22	R&S [®] SMAB-K27	1420.9749.02
AM/FM/φM	R&S [®] SMAB-K720	1420.9790.02
Scan AM ²³	R&S [®] SMAB-K721	1420.9784.02
Chirp signal generation ²⁴	R&S [®] SMAB-K725	1420.9861.02
Additional performance options		
Power analysis	R&S [®] SMAB-K28	1420.9755.02
Ramp sweep	R&S [®] SMAB-B28	1420.6579.02
Differential clock synthesizer 3 GHz	R&S [®] SMAB-B29	1420.8088.02
Clock synthesizer frequency extension to 6 GHz (not available for instruments equipped with R&S [®] SMAB-B103)	R&S [®] SMAB-K722	1420.9810.02
High dynamic uninterrupted level sweep 25	R&S [®] SMAB-K724	1420.9832.02
Other options		
Rear panel connectors (3 GHz/6 GHz)	R&S [®] SMAB-B80	1420.6504.02
Rear panel connectors (12.75 GHz/20 GHz/31.8 GHz/40 GHz), PC 2.92 mm	R&S [®] SMAB-B81	1420.6510.02
Rear panel connectors (50 GHz/67 GHz), PC 1.85 mm	R&S [®] SMAB-B82	1420.6527.02
Removable mass storage	R&S [®] SMAB-B85	1420.6556.02
Remote control GPIB and USB	R&S [®] SMAB-B86	1420.6562.02
Spare SD card	R&S [®] SMAB-Z10	1420.6662.02
Recommended extras		
19" rack adapter for 2 HU model	R&S [®] ZZA-KNP21	1177.8803.00
19" rack adapter for 3 HU model	R&S [®] ZZA-KNP31	1177.8810.00
Transport case for 2 HU and 3 HU model	R&S [®] ZZK-CASE	1174.1443.02
USB serial adapter, for RS-232 remote control	R&S [®] TS-USB1	6124.2531.00
Adapters for instruments with an R&S [®] SMAB-B112/-B120/-B131/-B140	O(N) frequency option	
Test port adapter, 2.4 mm female		1088.1627.02
Test port adapter, 2.92 mm female		1036.4790.00
Test port adapter, 2.92 mm male		1036.4802.00
Test port adapter, N female		1036.4777.00
Test port adapter, N male		1036.4783.00
Adapter for instruments with an R&S®SMAB-B150(N)/-B167(N) frequer	ncy option	1
Wear and tear adapter, 1.85 mm female/female	· · ·	3588.9654.00
Documentation	1	
Documentation of calibration values	R&S [®] DCV-2	0240.2193.18
R&S [®] SMA100B accredited calibration; up to 6 GHz	R&S®ACASMA100B	3598.3307.03
R&S [®] SMA100B accredited calibration; 12.75 GHz to 40 GHz	R&S®ACASMA100B	3598.3236.03
R&S®SMA100B accredited calibration: 50 GHz to 67 GHz	R&S [®] ACASMA100B	3598.3207.03

²² Requires R&S[®]SMAB-K23 pulse generator option.

²³ Requires R&S[®]SMAB-K720 AM/FM/φM option. For instruments with a serial number < 102000, please contact the Rohde & Schwarz service department.</p>

²⁴ Requires R&S[®]SMAB-K22 high performance pulse modulator option, R&S[®]SMAB-K23 pulse generator option and R&S[®]SMAB-K720 AM/FM/φM option. FW version > 4.70.xxx required.

²⁵ For instruments with a serial number < 102000, please contact the Rohde & Schwarz service department.

Warranty		
Base unit		3 years
All other items ²⁶		1 year
Service options		
Extended warranty, one year	R&S [®] WE1	Please contact your local Rohde & Schwarz sales office.
Extended warranty, two years	R&S [®] WE2	
Extended warranty with calibration coverage, one year	R&S [®] CW1	
Extended warranty with calibration coverage, two years	R&S [®] CW2	
Extended warranty with accredited calibration coverage, one year	R&S [®] AW1	
Extended warranty with accredited calibration coverage, two years	R&S [®] AW2	

Extended warranty with a term of one and two years (WE1 and WE2)

Repairs carried out during the contract term are free of charge ²⁷. Necessary calibration and adjustments carried out during repairs are also covered.

Extended warranty with calibration coverage (CW1 and CW2)

Enhance your extended warranty by adding calibration coverage at a package price. This package ensures that your Rohde & Schwarz product is regularly calibrated, inspected and maintained during the term of the contract. It includes all repairs ²⁷ and calibration at the recommended intervals as well as any calibration carried out during repairs or option upgrades.

Extended warranty with accredited calibration (AW1 and AW2)

Enhance your extended warranty by adding accredited calibration coverage at a package price. This package ensures that your Rohde & Schwarz product is regularly calibrated under accreditation, inspected and maintained during the term of the contract. It includes all repairs ²⁷ and accredited calibration at the recommended intervals as well as any accredited calibration carried out during repairs or option upgrades.

²⁶ For options that are installed, the remaining base unit warranty applies if longer than 1 year. Exception: all batteries have a 1 year warranty.

²⁷ Excluding defects caused by incorrect operation or handling and force majeure. Wear-and-tear parts are not included.

Service that adds value

- Local and personalized
 Customized and flexible
 Uncompromising quality
 Long-term dependability

Rohde & Schwarz

The Rohde&Schwarz technology group is among the trailblazers when it comes to paving the way for a safer and connected world with its leading solutions in test&measurement, technology systems and networks & cybersecurity. Founded more than 85 years ago, the group is a reliable partner for industry and government customers around the globe. The independent company is headquartered in Munich, Germany and has an extensive sales and service network with locations in more than 70 countries.

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- Environmental compatibility and eco-footprint
- Energy efficiency and low emissions
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